

ICMAB

INSTITUT DE CIÈNCIA DE
MATERIALS DE BARCELONA

Xavier Obradors
Director ICMAB – CSIC



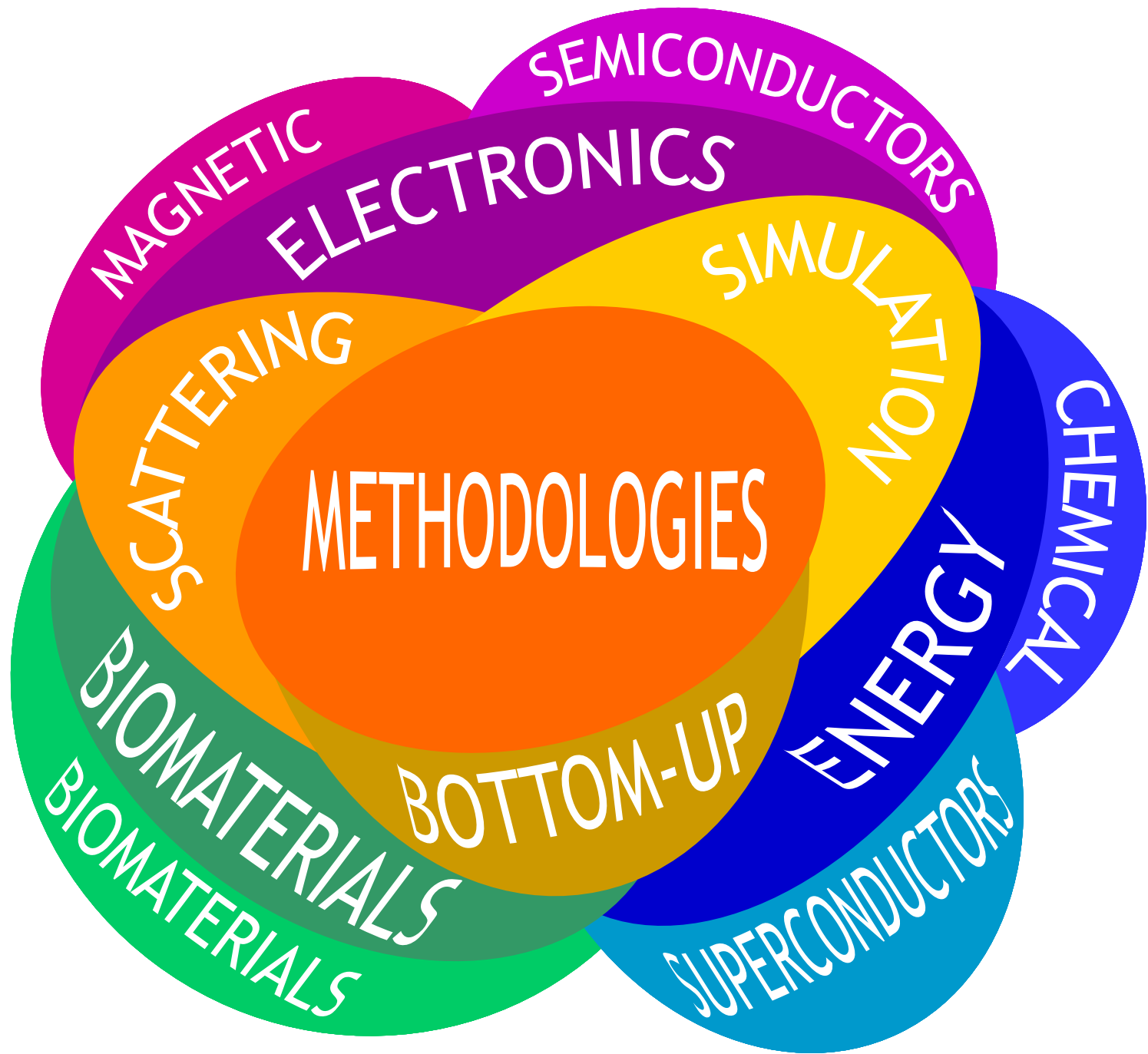
CONSEJO SUPERIOR DE INVESTIGACIONES CIENTÍFICAS

Where are we?



ICMAB RESEARCH ACTIVITIES

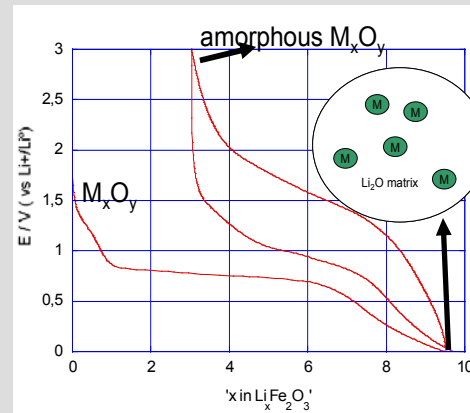




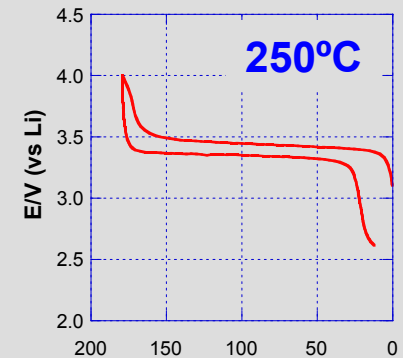
New materials, alternative mechanisms



PCT application ES03/00249
J. Electrochem. Soc. 152(11), (2005)
Inorg. Chem. (submitted)

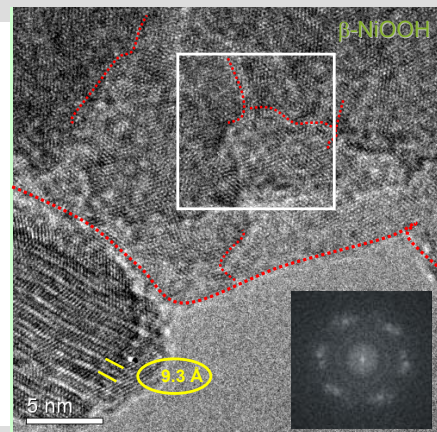
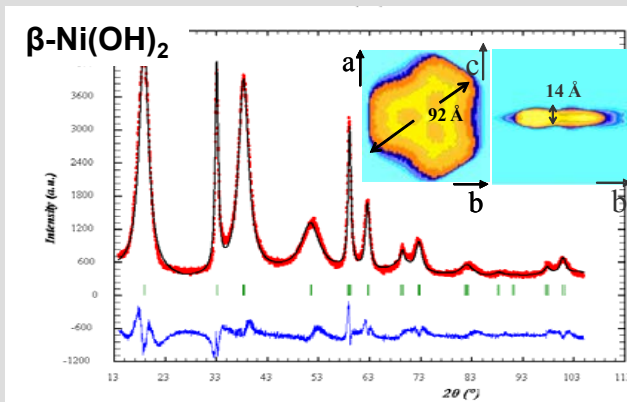


High T batteries

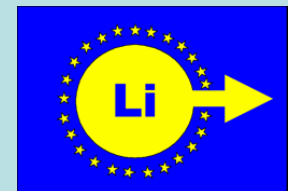


Electrochem. Comm. 9, 708 (2007))

Correlation microstructure-electrochemical yield



Journal of the American Chemical Society, 129, 5840 (2007)
Journal of Materials Chemistry 16, 2925 (2006)



ALISTORE ERI

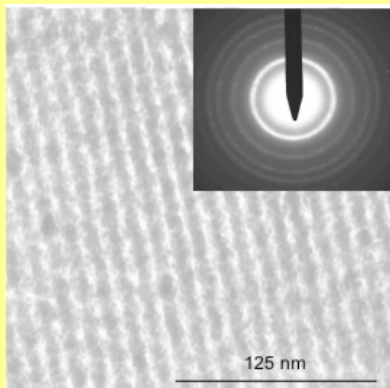
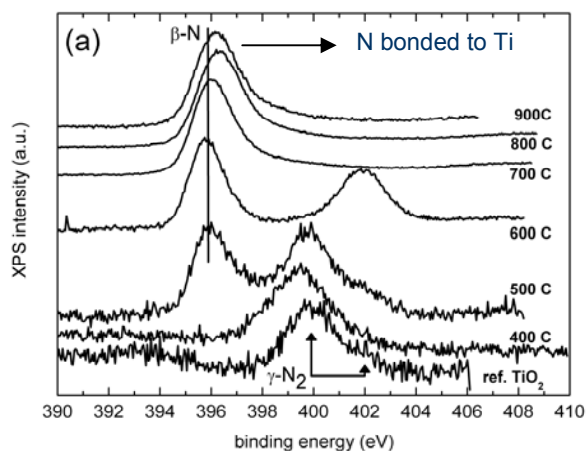


Nitride materials with photocatalytical activity in the visible range

Nitrogen doping of oxides decreases the band gap because of the lower electronegativity of N vs O, shifting the photocatalytical activity from the UV to the visible range

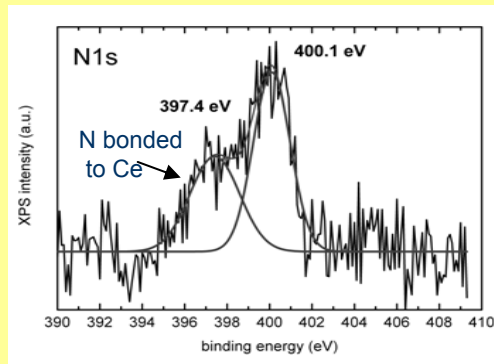
Mesoporous nanostructured thin films of $\text{TiO}_{2-x-y}\text{N}_x$ (anatase)

N1s XPS as a function of the nitriding temperature in NH_3



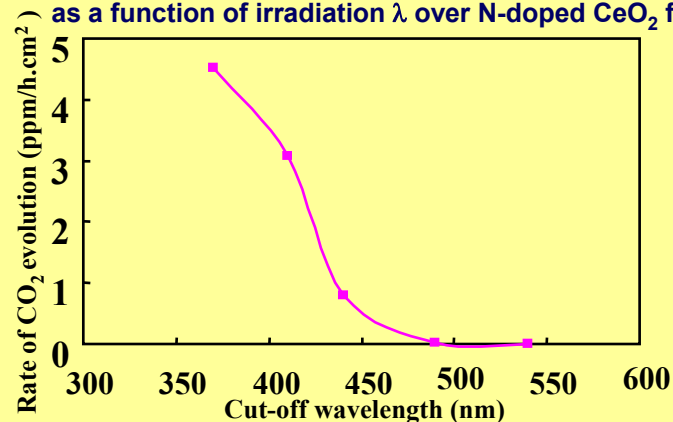
The mesostructure is kept until $T=700^\circ\text{C}$

New nitrogen doped ceria ($\text{CeO}_{2-x-y}\text{N}_x$) with photocatalytical activity in the visible range



Solid solution $\text{CeO}_{2-x-y}\text{N}_x$ up to 4.5 mol % N

Rate of CO_2 evolution for decomposition of acetaldehyde as a function of irradiation λ over N-doped CeO_2 films

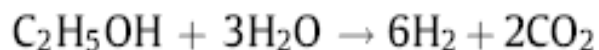


Chemistry of Materials, 2, 1682 (2008)
A.Fuertes, A.B.Jorge. Pat. Esp. 200700482. 23-02-2007.

Hydrogen by Ethanol Reforming

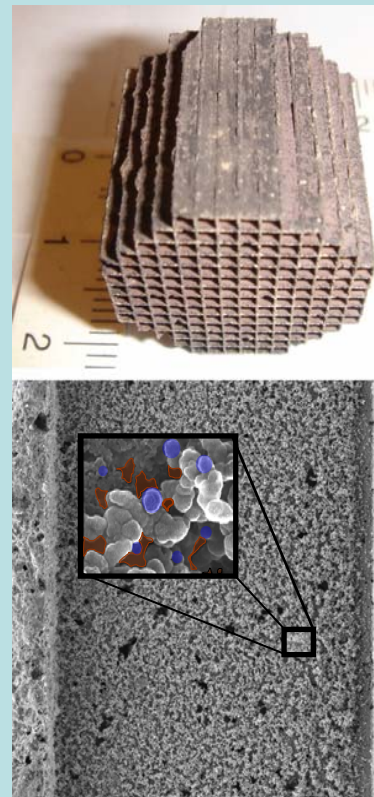
Catalyst grown on cordierite substrate: Nanocomposited silica aerogel with cobalt nanoparticles (blue in the idealized inset).

The catalytic device can be simply heated up to the reaction temperature (320-340°C) under air, and then the ethanol is introduced for the generation of hydrogen.



This has a strong potential for fuel cell technology as well as for on-board generation of hydrogen for mobile applications.

The catalytic device can be easily operated and doesn't require special care for shut down cycles, thus allowing interrupted and/or oscillating operation for real practical application. No activation and/or conditioning are required for operation.



Co-SiO₂ aerogel-coated catalytic walls for the generation of hydrogen, M.Domínguez, E.Taboada, E.Molins, J.Llorca, Catalysis Today (2008) and CSIC-UPC patent (2007)



Consolider



ICMAB



Chemical solution approaches to self-assembled and nanocomposite superconducting films

Xavier Obradors

T.Puig, A. Pomar, A. Palau, F. Sandiumenge, S. Ricart, N. Mestres, J. Gutiérrez, M. Gibert, A. Llordés, A. Carretero, C. Moreno, R.F. Luccas, J. Zabaleta, F. Martínez, P. Abellán, N. Romà, A. Benedetti, J. Gázquez, M. Coll, R. Vlad, X.Granados

***Institut de Ciència de Materials de Barcelona,
CSIC, 08193 Bellaterra, Spain***

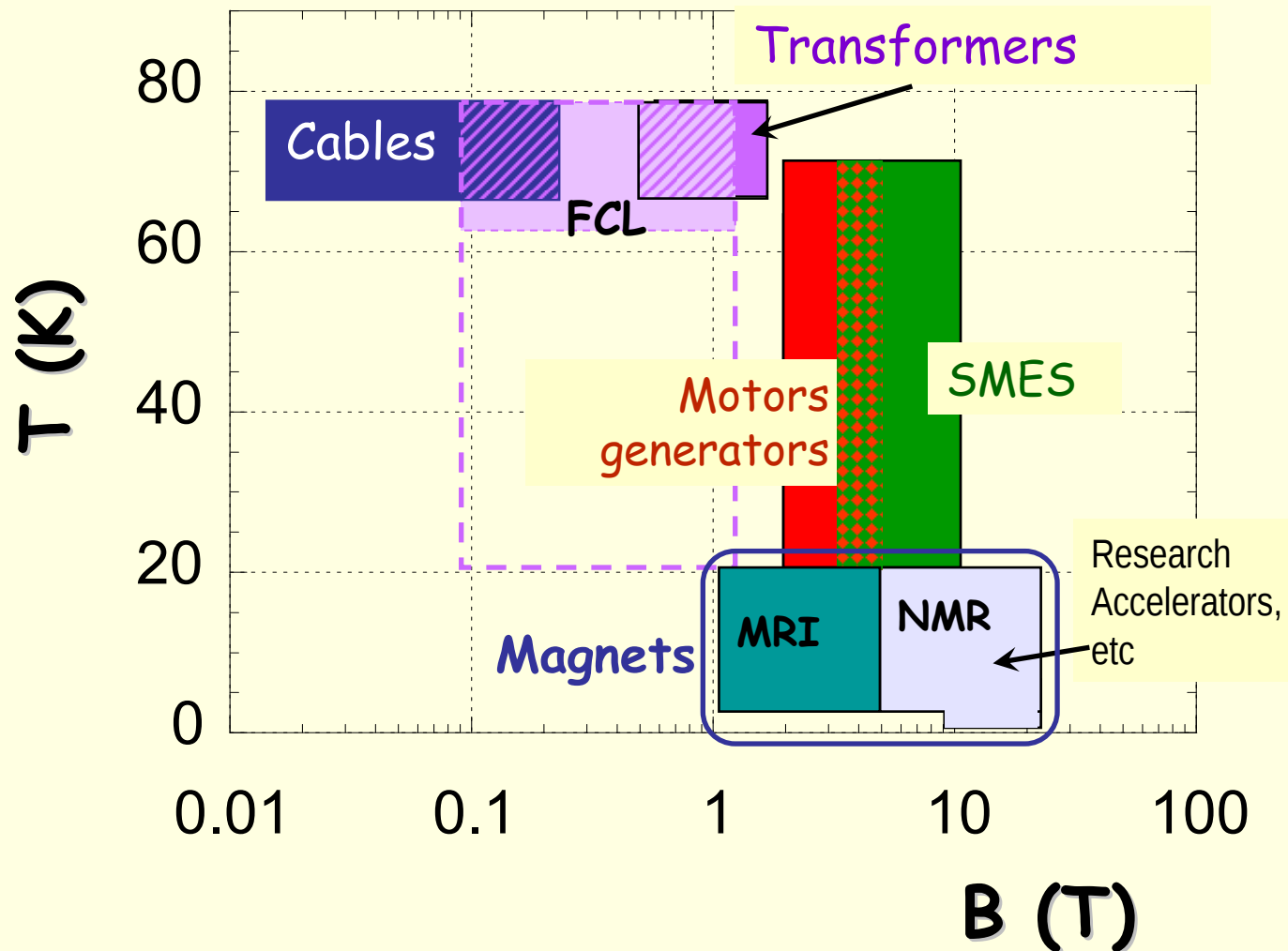
HIPERCHEM



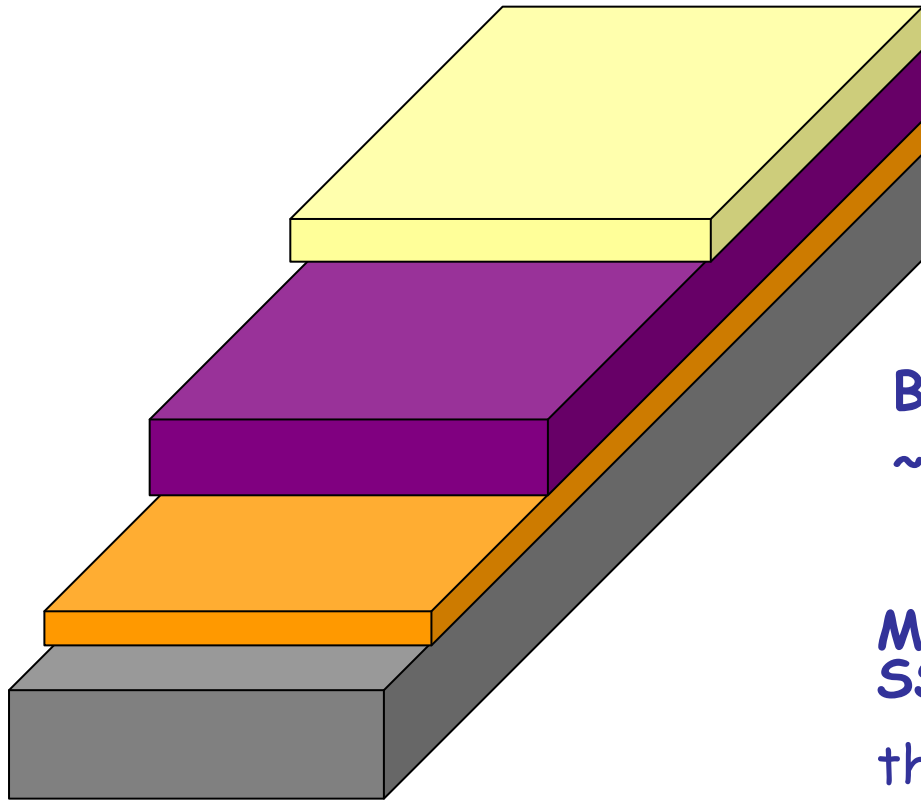
ESAS

The European Society for
Applied Superconductivity

POWER APPLICATIONS SUPERCONDUCTORS



COATED CONDUCTORS ARCHITECTURE



Cap layer : Ag

thickness $\approx 0.2 - 0.5 \mu\text{m}$

SC layer : YBCO

$\sim 1.0 \mu\text{m}$

Buffer layers : CeO_2 , YSZ, STO,...
 $\sim 0.1 \mu\text{m}$

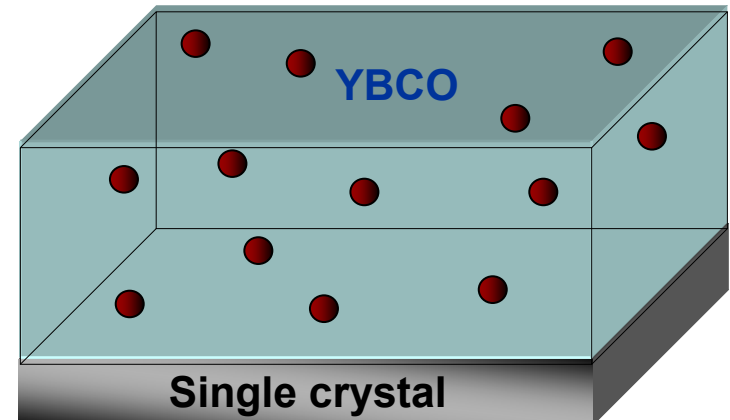
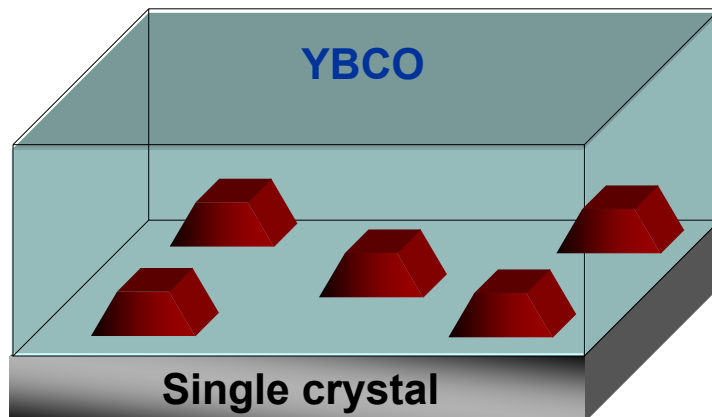
Metallic substrate: RABiTS Ni,
SS-IBAD

thickness $\sim 80 \mu\text{m}$

Nanostructure control on km length materials

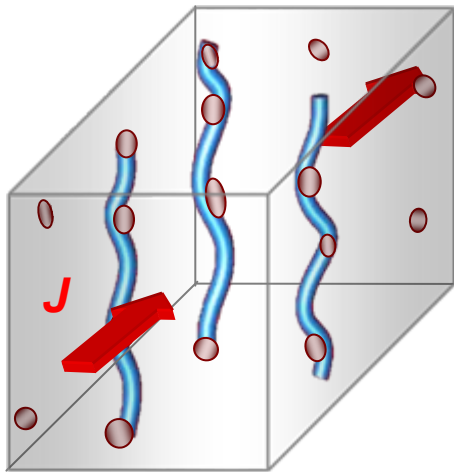
GOALS

- The potentiality and richness of chemical solution methods for growth of nanostructured films and coated conductors:
 - A flexible, scalable and controllable bottom-up approach
- Nanostructured YBCO films by chemical routes
 - Interfacial nanostructured films
 - Nanocomposites
 - Ferromagnetic-superconductor nanostructured YBCO films
- Methodology to analyze vortex pinning based on angular dependent transport J_c measurements



APS : Artificial Pinning Structures

**Pinning of vortices
by material defects**



$$F_L = J_c \times B = F_p \rightarrow v_{fl} = 0$$

Current flow without
dissipation

⇒ **Generation of APS**

HOW ?

... by nanostructuration

The methodology must be versatile, scalable and low cost

We choosed a chemical solution route

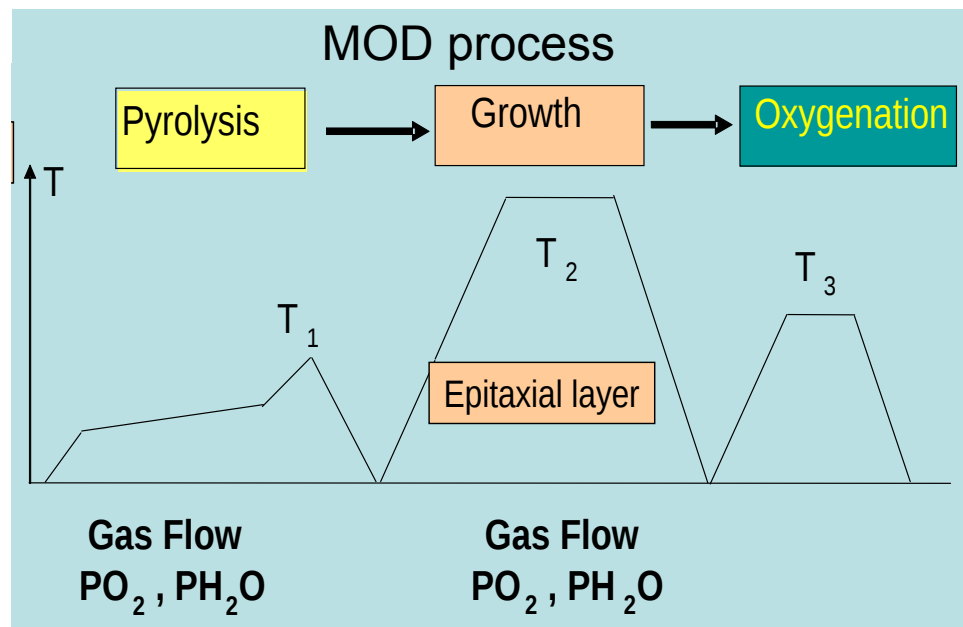
NEED of:

- Manipulation, control and tuning of APS
- Correlation of nanostructured films with J_c
- Knowledge on superposition of APS and natural defects
- More realistic theoretical pinning models considering complexity

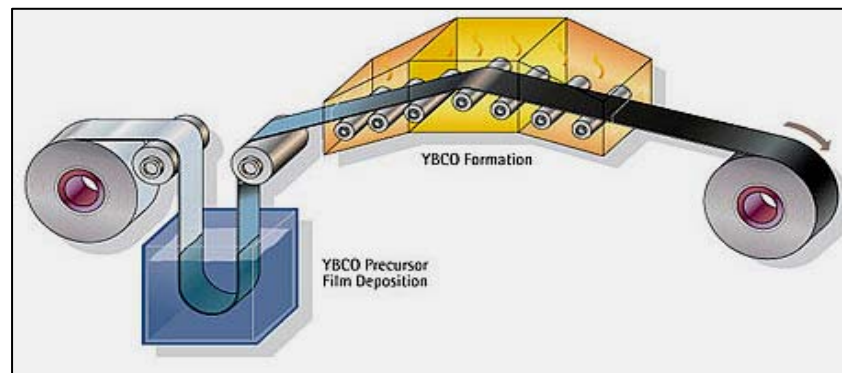
Chemical Solution Deposition

... a versatile, scalable and low cost methodology for growth of nanostructured films

For YBCO films ...



Coated conductors

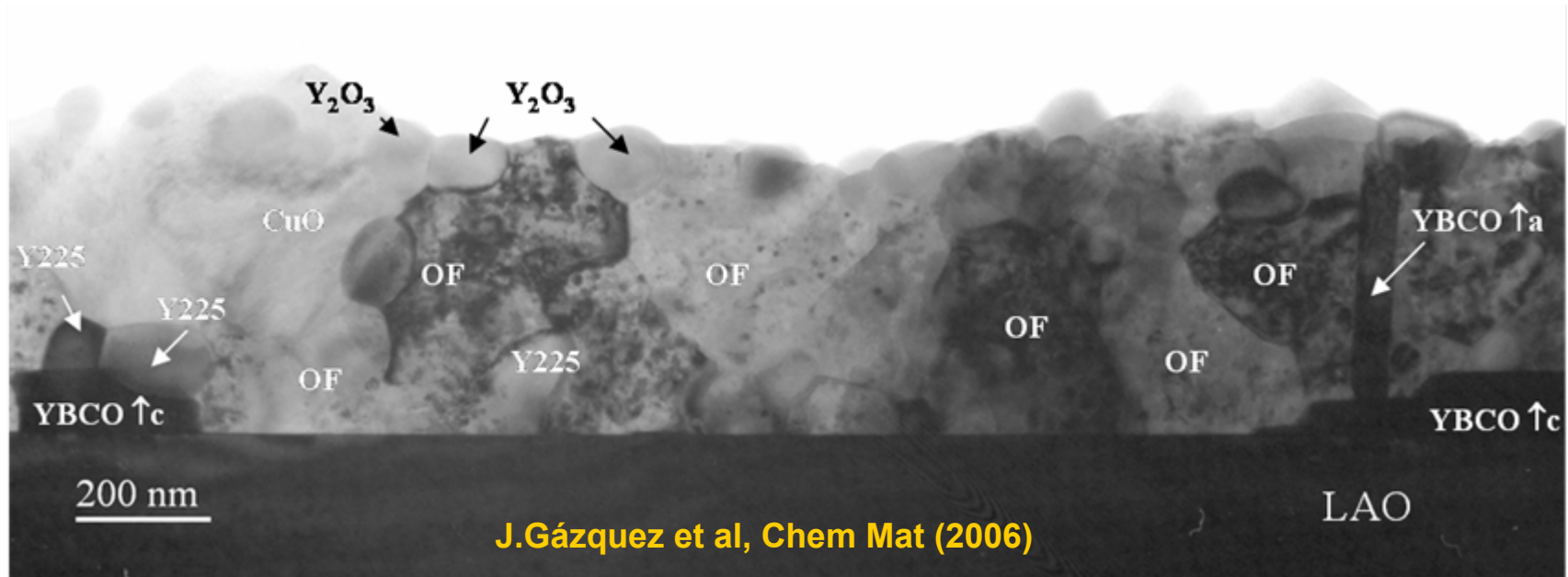


- **Low-cost methodology**
- **High production rate**
- **Scalable to large surfaces**
- **Versatile: nanostructuration**

Phase and growth control

Film quenched before growth

- Intermediate phases: α - Y_2O_3 , $\text{Y}_2\text{Cu}_2\text{O}_5$ and CuO embedded in oxyfluorides (OF)
- YBCO nucleates exclusively at the interface: island to layer growth

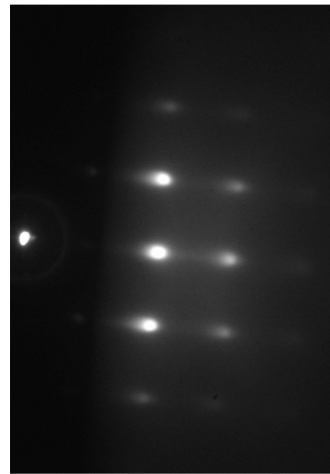


Y long and winding road: $\text{TFA-Y} / \text{Ba}_{1-x}\text{Y}_x\text{F}_2 / \alpha\text{-Y}_2\text{O}_3 / \text{Y}_2\text{Cu}_2\text{O}_5 / \text{Ba}_{1-x}\text{Y}_x(\text{F},\text{O})_{2-y} / \text{YBa}_2\text{Cu}_3\text{O}_7$

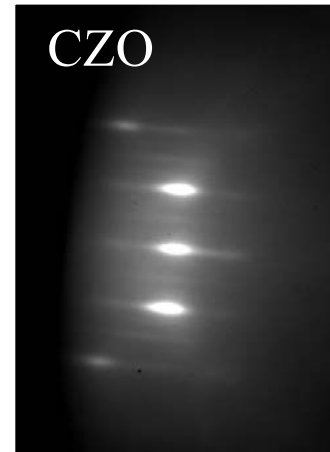
Multilayers: Epitaxy and cap layer planarity



RHEED



High energy
(00l) facets



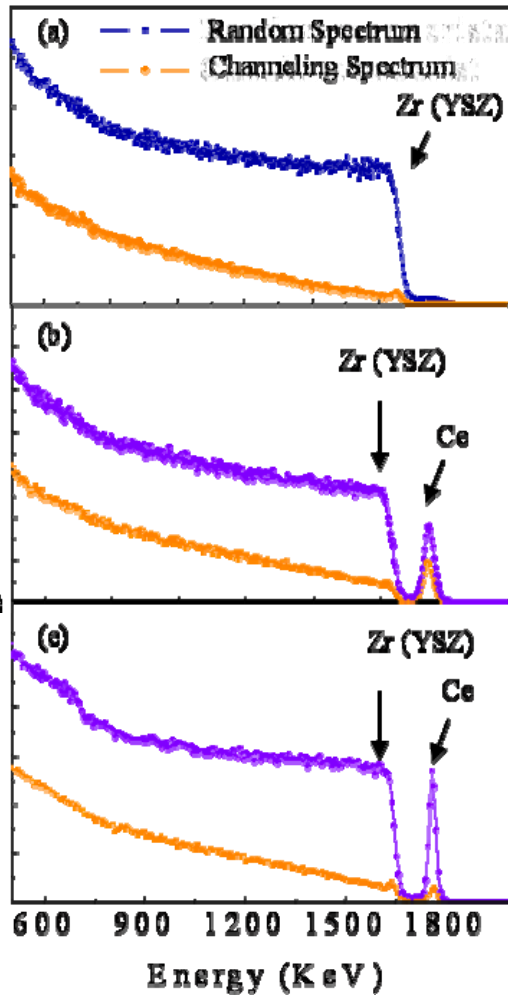
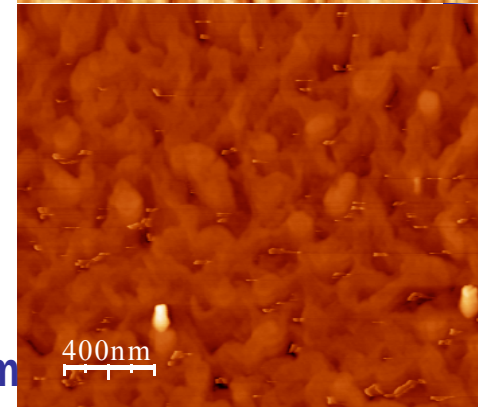
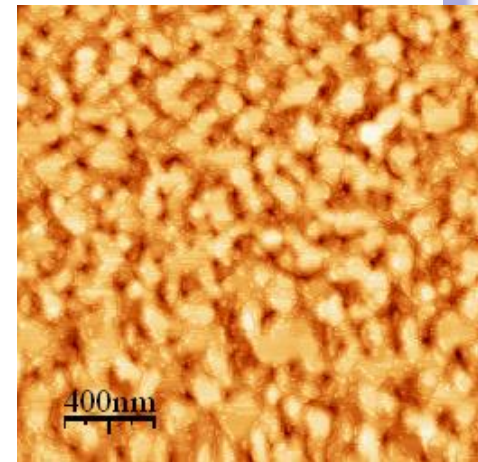
RBS channeling

$$\chi_{\min} = 12 \% (\text{CeO}_2)$$

$$\chi_{\min} = 46 \% (\text{CZO})$$

AFM

rms: 3 nm

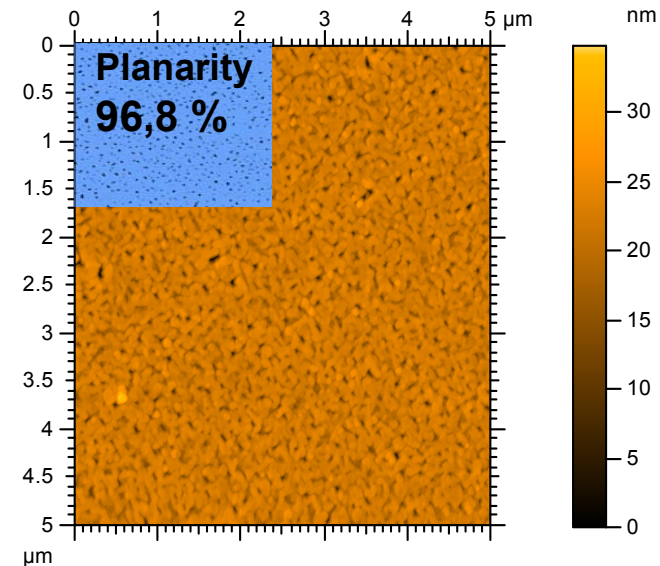
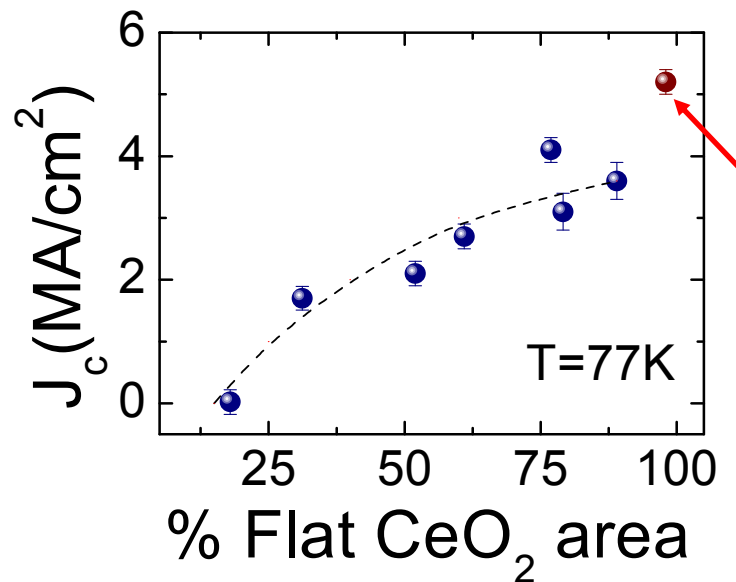
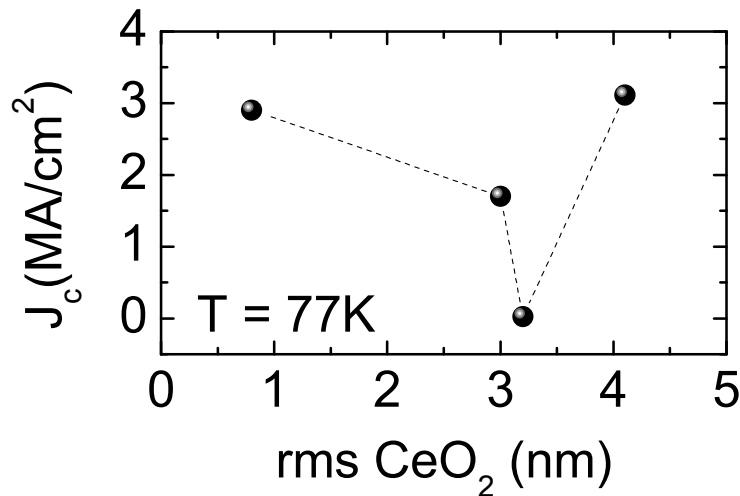


rms: 0.8nm

Growth of TFAYBCO on MOD CeO_2 cap layers

rms roughness is too rough

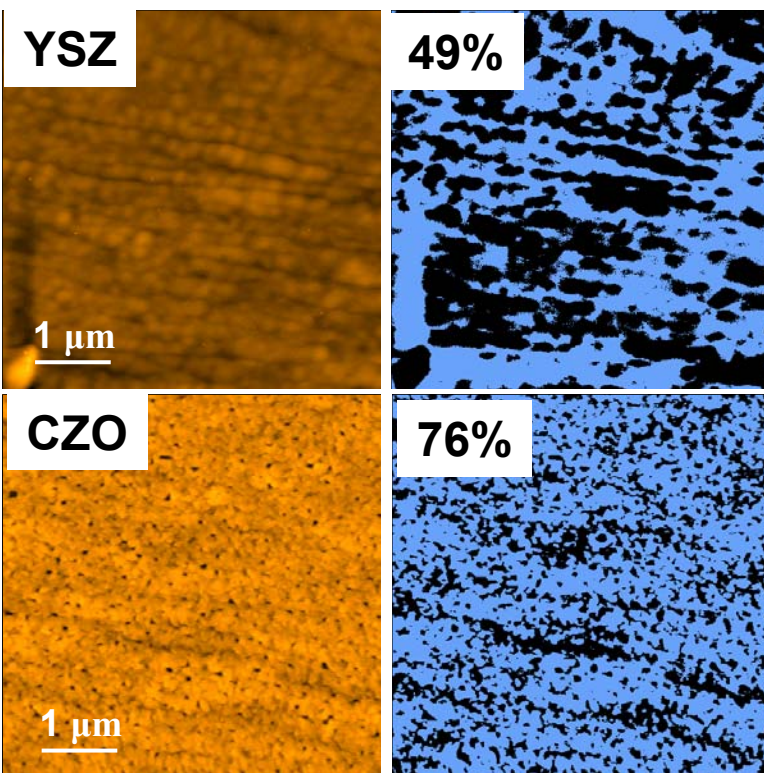
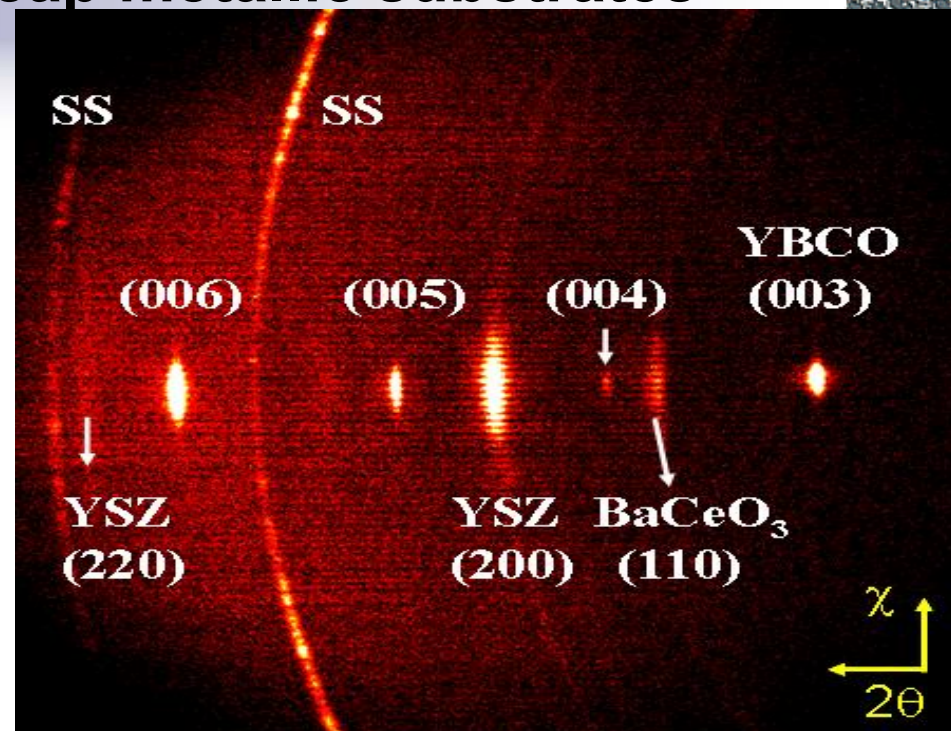
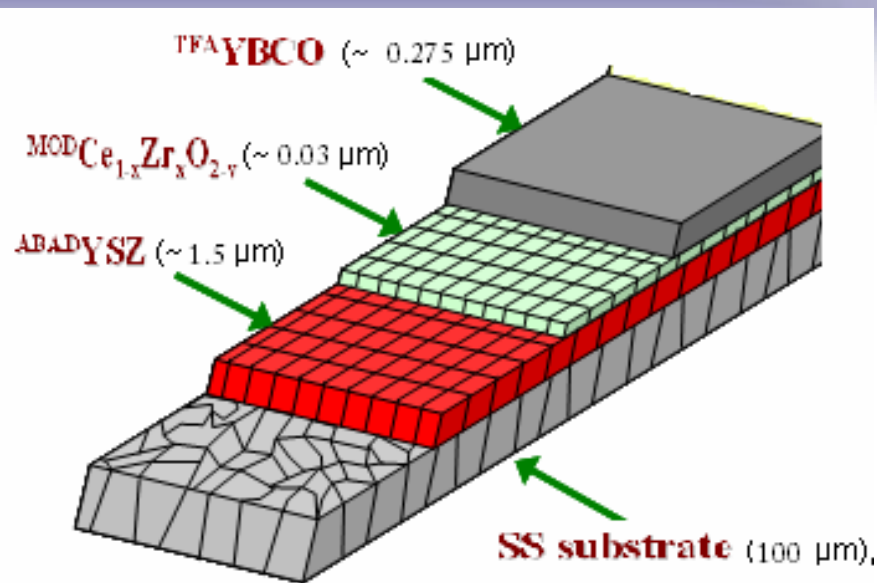
Surface planarity is more useful



J_c (77K) = 5.2 MA/cm²

**Highest critical current
 TFAYBCO on MOD- CeO_2
cap layers**

Growth of TFEYBCO on MOD-cap metallic substrates



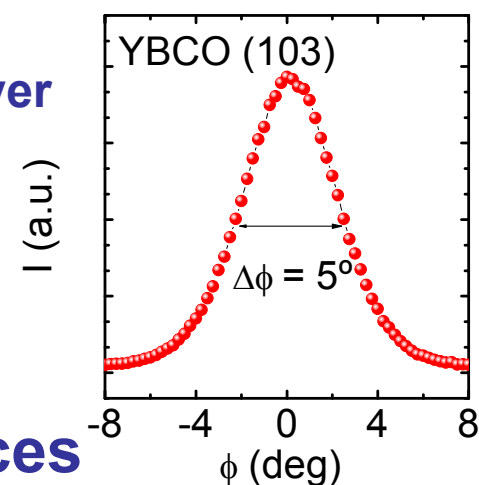
Polycrystalline
substrate/epitaxial multilayer

$$\Delta\phi (\text{YBCO}) = 5^\circ$$

$$\Delta\phi (\text{YSZ}) = 9.5^\circ$$

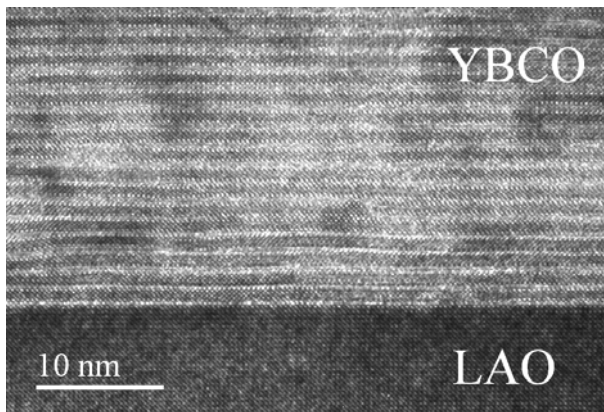
MOD planarization
High SC performances

$$J_c (77\text{K}) = 1.8 \text{ MA/cm}^2$$



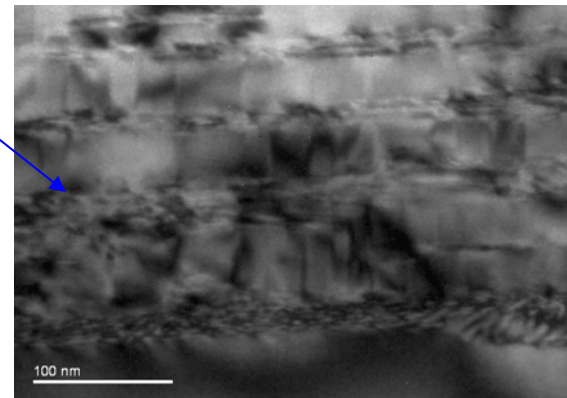
Vortex pinning in MOD-YBCO films

High quality epitaxial films
 $J_c^{sf}(77K) \sim 4 \text{ MA/cm}^2$

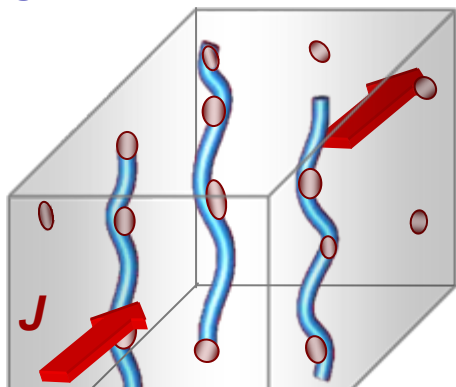


Island based nucleation and growth mode $\rightarrow$ a-b plane defects promotion

- Intergrowth
- Stacking faults
- in-plane partial dislocations



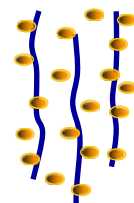
Critical current optimization $\rightarrow$ at high fields (1- 5T)



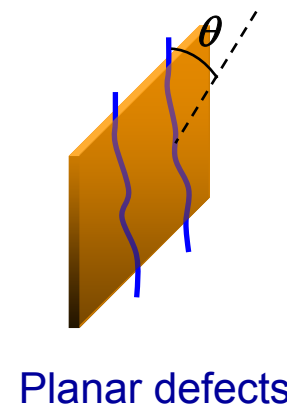
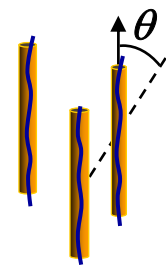
Correlation nanostructure and vortex pinning

Pinning defects of specific size and disposition

Point like defects

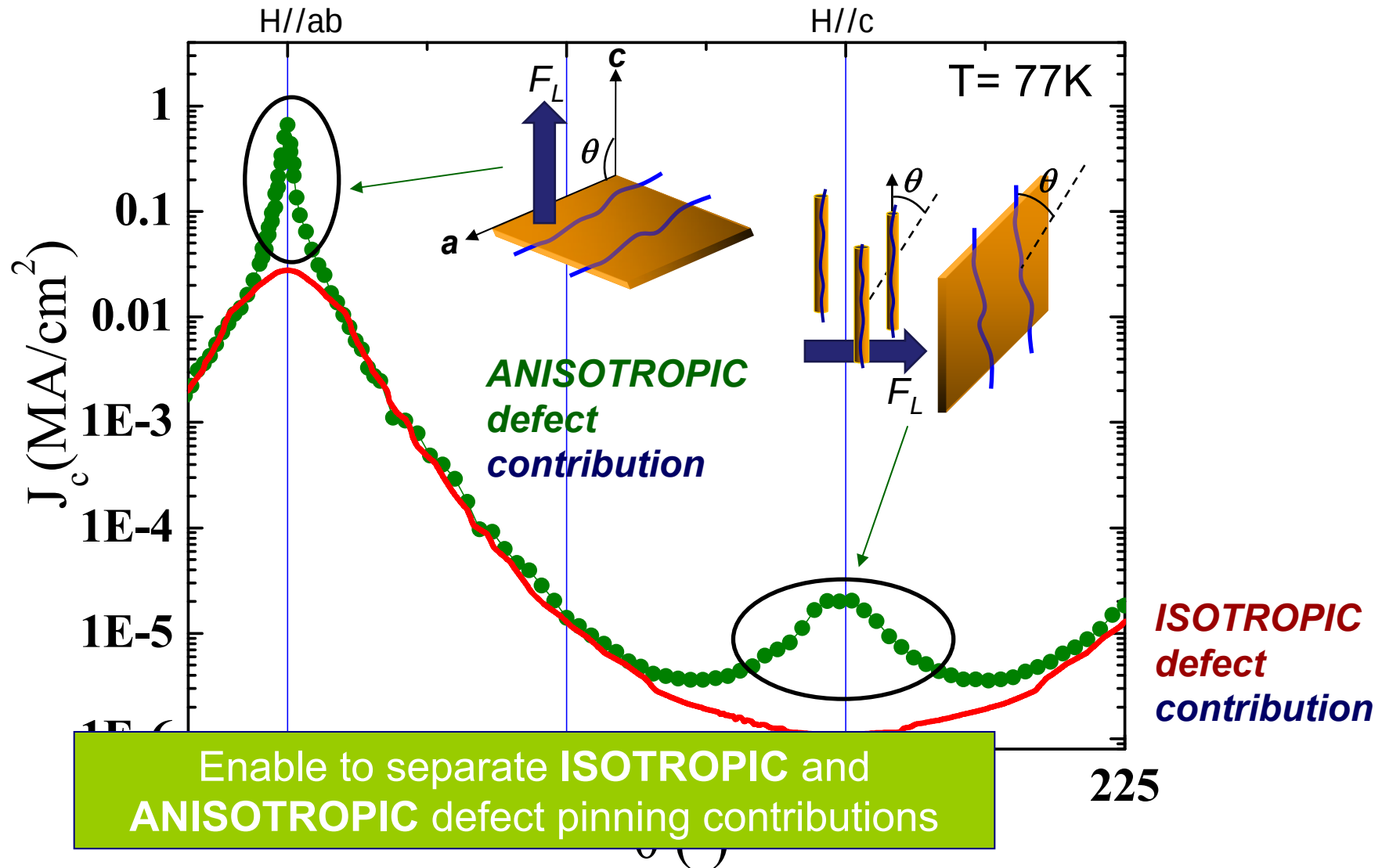


Linear defects

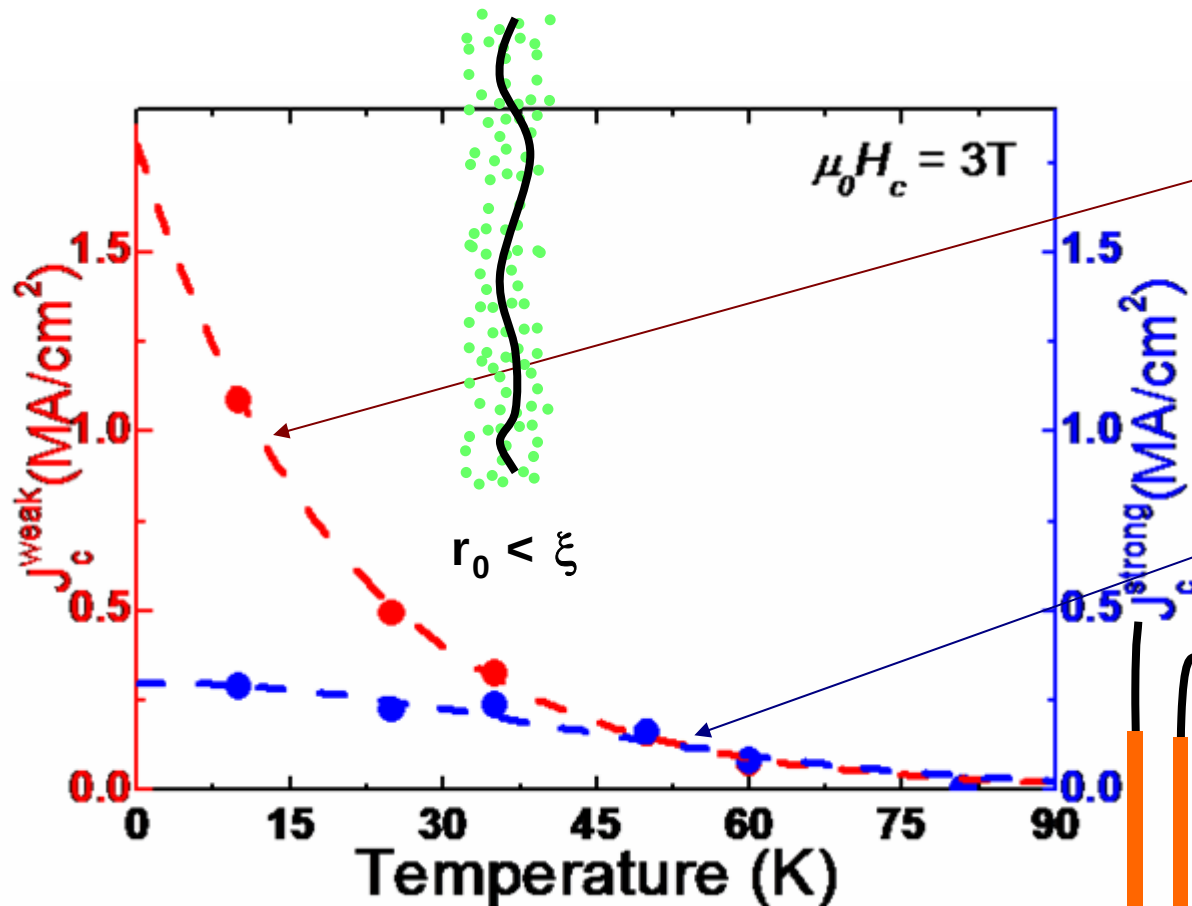


We need to identify and separate different vortex pinning contributions

Isotropic and anisotropic pinning defect contributions



J_c temperature dependence: Weak and strong pinning



PLD-YBCO

Weak pinning

$$J_c(T) = J_{c0}^{\text{wk}} e^{-T/T_0}$$

Blatter et al., *Rev. Mod. Phys* **66**
(1994)

Strong correlated pinning

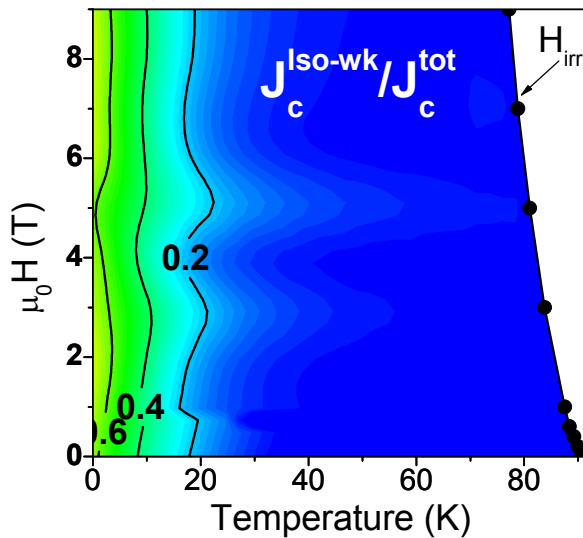
$$J_c(T) = J_{c0}^{\text{str}} e^{-3(T/T^+)^2}$$

Nelson et al, *Phys. Rew. B* **48**
(1993)

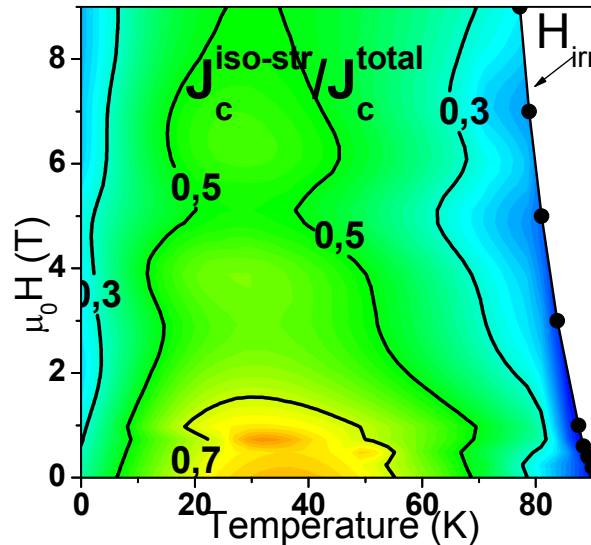
J.Gutierrez et al., *Appl. Phys. Lett.* **90** (2007)

Pinning regime diagrams in standard TFA films for H//c

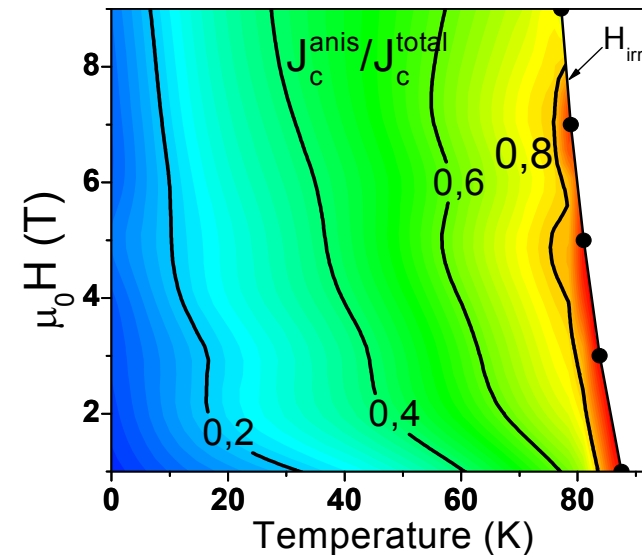
Iso-wk
contribution



Iso-str
contribution



Aniso-str
contribution



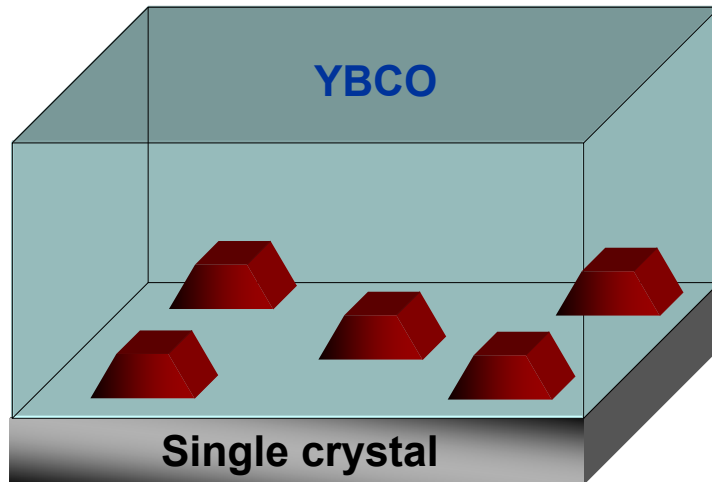
275 nm YBCO-TFA films

We have a tool to separate and quantify the three vortex pinning contributions

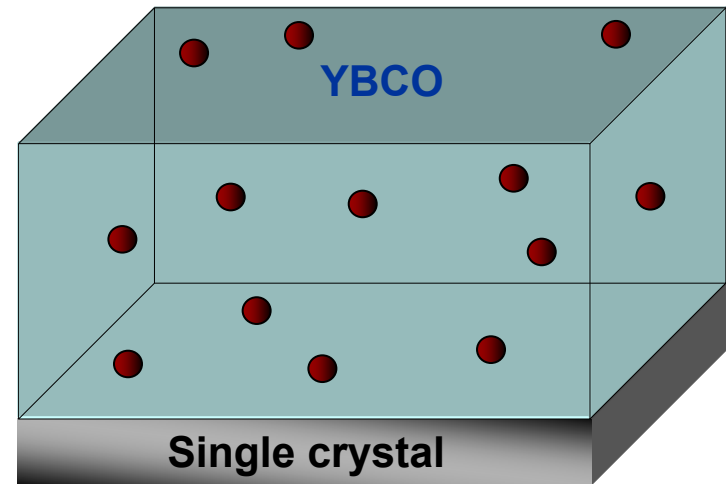
Weak-isotropic defects dominate at low T, **strong-isotropic** defects at intermediate T and **strong-anisotropic** defects at high T

Vortex pinning in nanostructured YBCO-TFA films

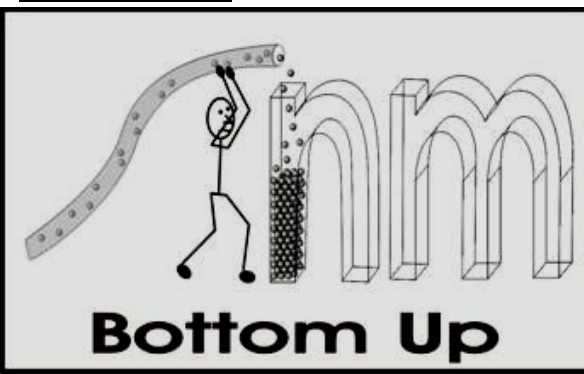
Interfacial nanostructured films:



Nanocomposite films:



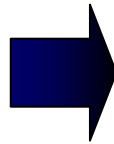
Approach:



AIM: Identify and control pinning contributions induced in the different nanostructured YBCO films

Nanostructures: Chemical Solution Deposition

Metal-organic
precursors



Spin-coating
on a substrate

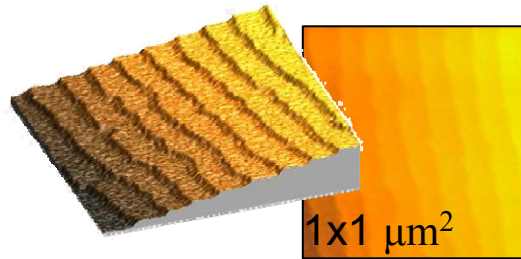


Thermal
treatment

Pentadionates, acetates, propionates
in acetic acid, isopropanol and/or
propionic acid

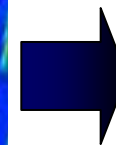
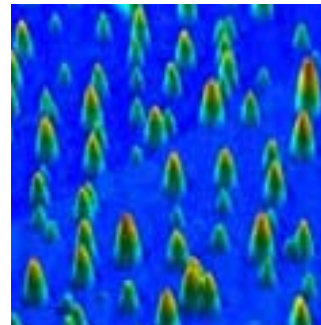
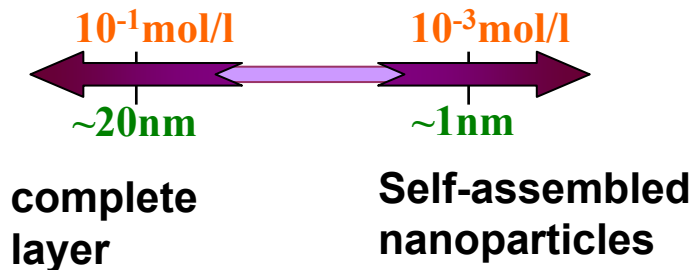
$600^{\circ}\text{C} \leq T \leq 1000^{\circ}\text{C}$

Atm: O_2 , Ar-H_2



single crystal
thermally treated

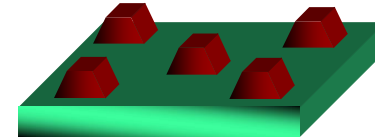
Use of very dilute solutions → **Tune of the equivalent deposited thickness through concentration**



Surface energy
Interface energy
Elastic relaxation energy

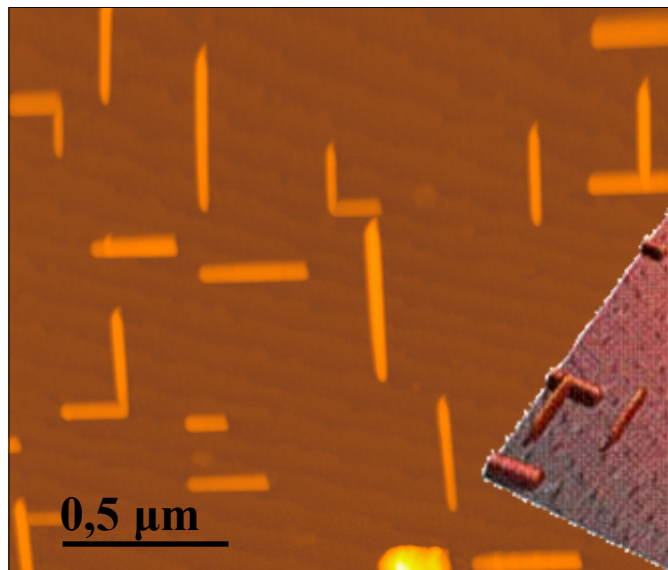
Interfacial self-assembled nanostructured films

Self-assembled nanostructures grown from chemical methods

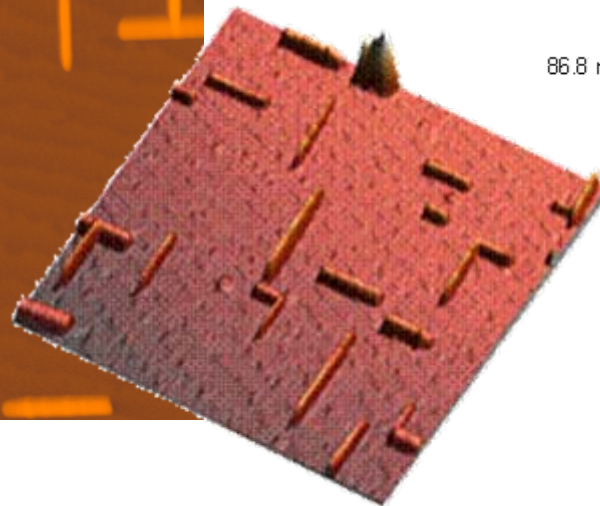
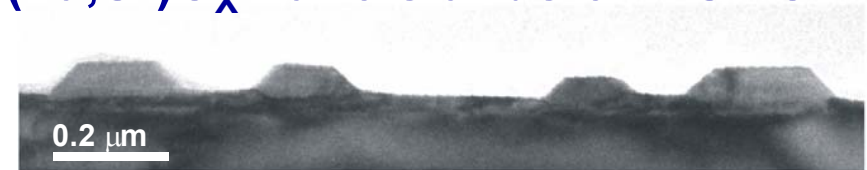


➤ Strain induced self-assembled $\text{Ce}_{0.9}\text{Gd}_{0.1}\text{O}_{2-y}$ nanowalls

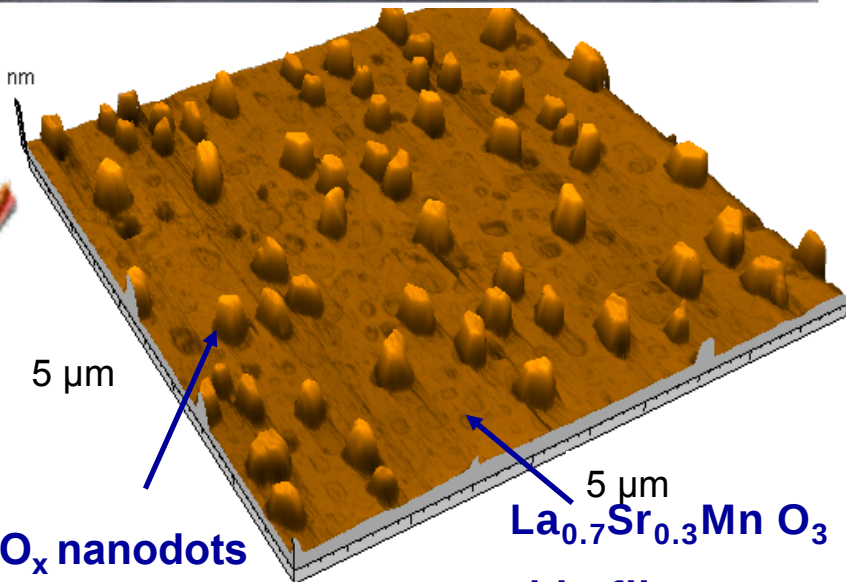
➤ Spontaneous nucleation of $(\text{La,Sr})\text{O}_x$ nanoislands on LSMO



$h \sim 8-10 \text{ nm}$



$(\text{La,Sr})\text{O}_x$ nanodots
 $h \sim 50 \text{ nm}$



$\text{La}_{0.7}\text{Sr}_{0.3}\text{MnO}_3$
thin film

M. Gibert et al., Adv. Mat. 19, 3937 (2007)

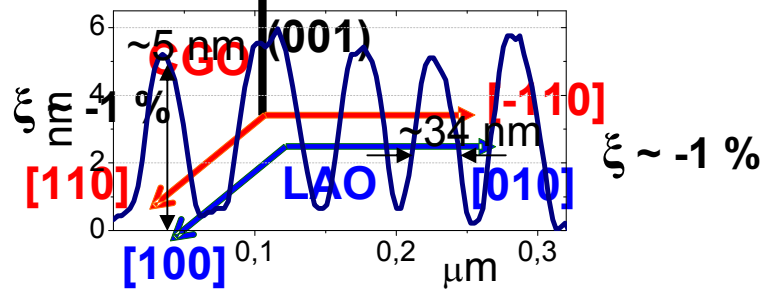
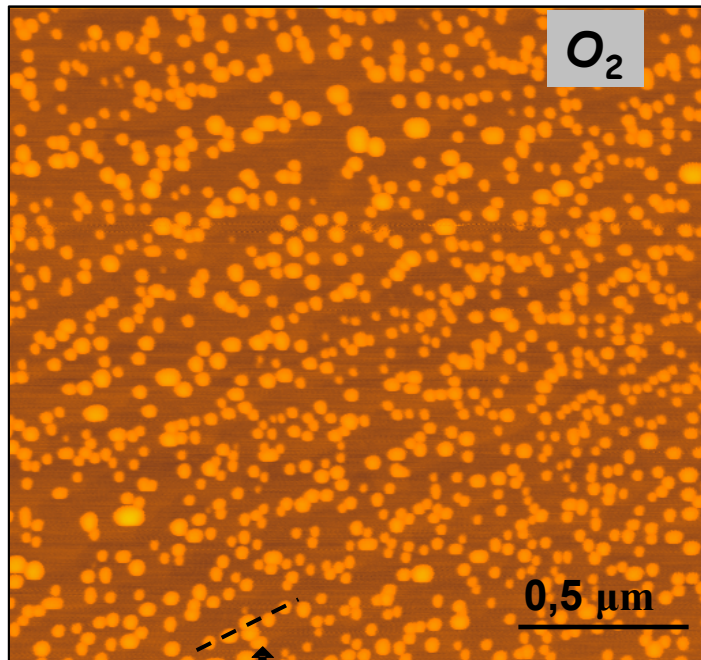
C. Moreno et al. Adv.Func.Mat. (2009)

Nanodot and nanowires of $\text{Ce}_{0.9}\text{Gd}_{0.1}\text{O}_{2-y}$

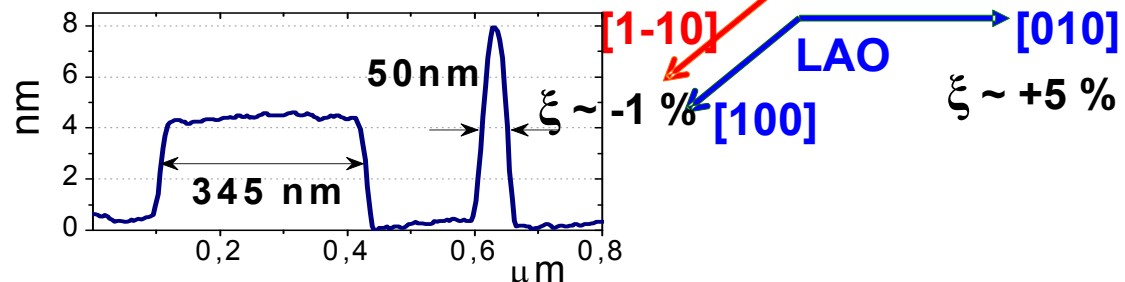
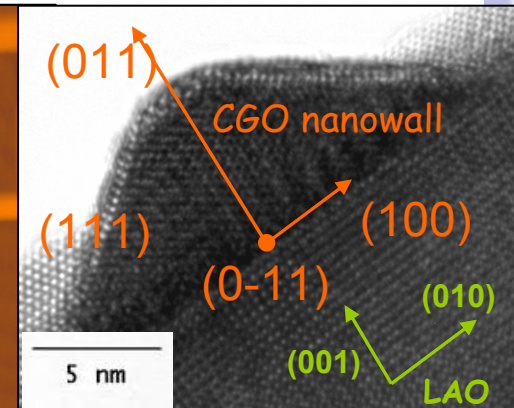
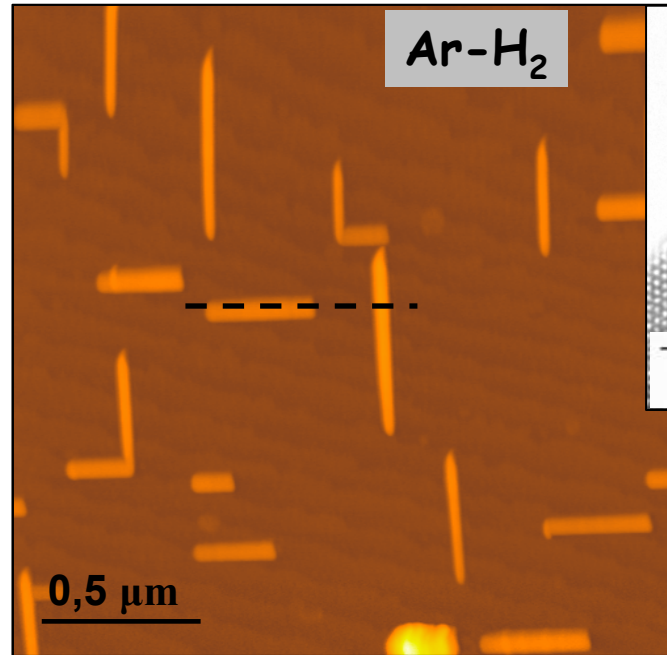


Growth atmosphere: fine selection of interface energy

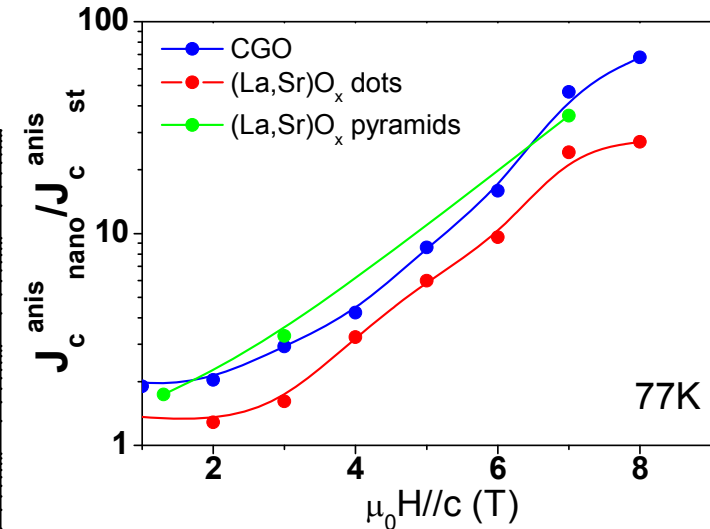
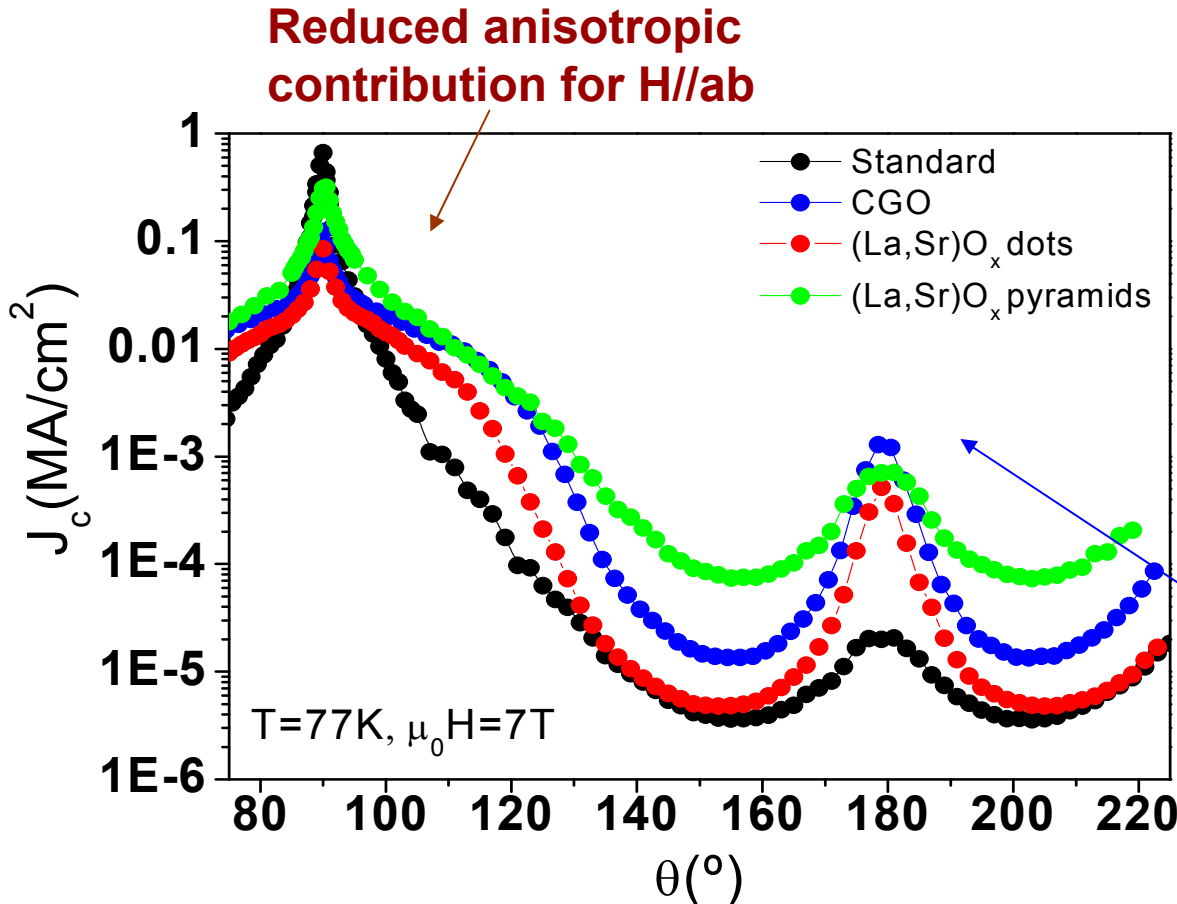
Isotropic islands



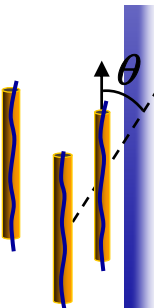
Highly anisotropic islands



Interfacial oxide nanostructured films: Anisotropy of $J_c(\theta)$



c-axis anisotropic contribution is strongly increased

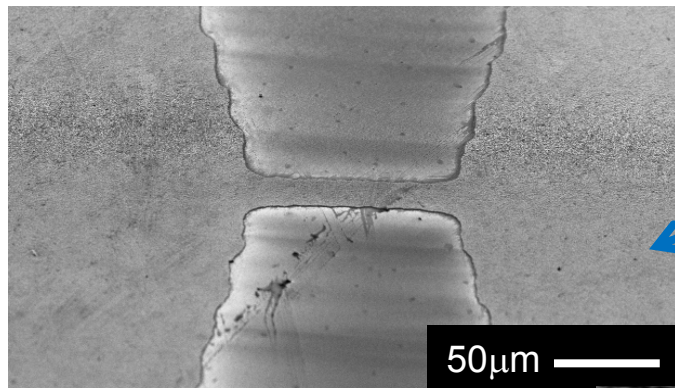
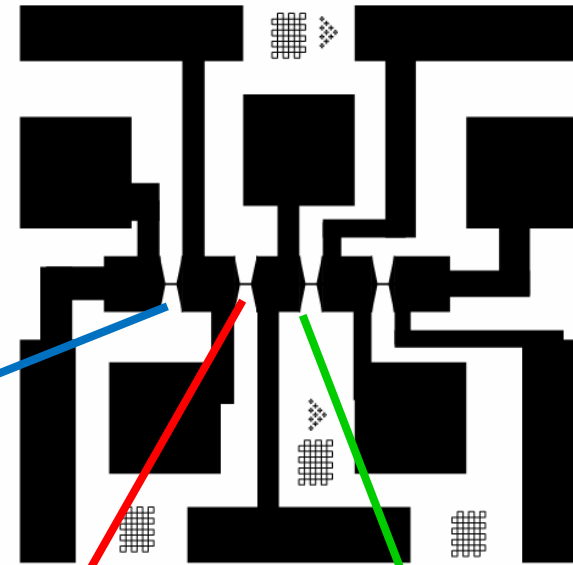


Similar behavior obtained for all the different architectures → defects along the c-axis induced in the YBCO matrix by the interfacial particles

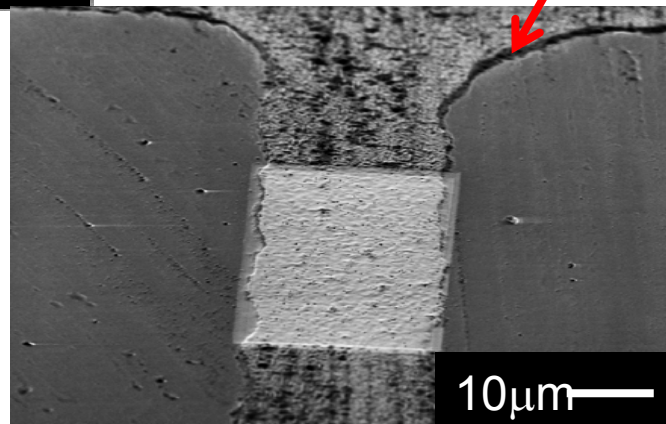
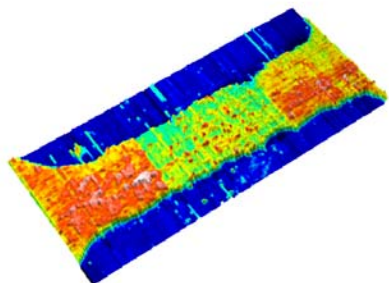
Interfacial oxide nanostructured films: thickness dependence

4 tracks (20 μm *100 μm)
defined by lithography:

YBCO/Ce_{0.9}Gd_{0.1}O_{2-y} nanowalls



Track 1: full thickness
250nm

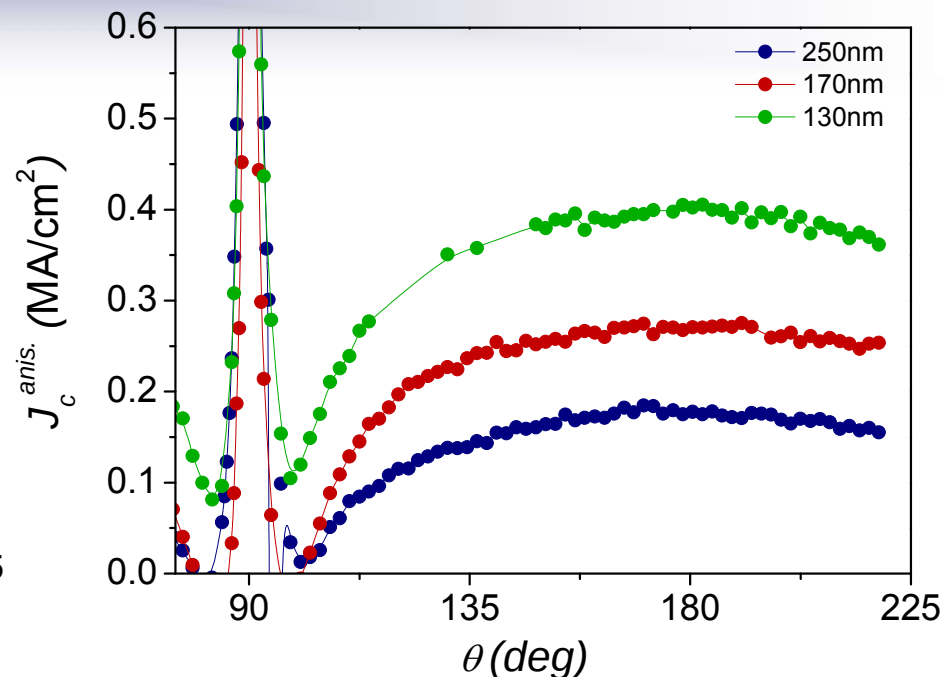
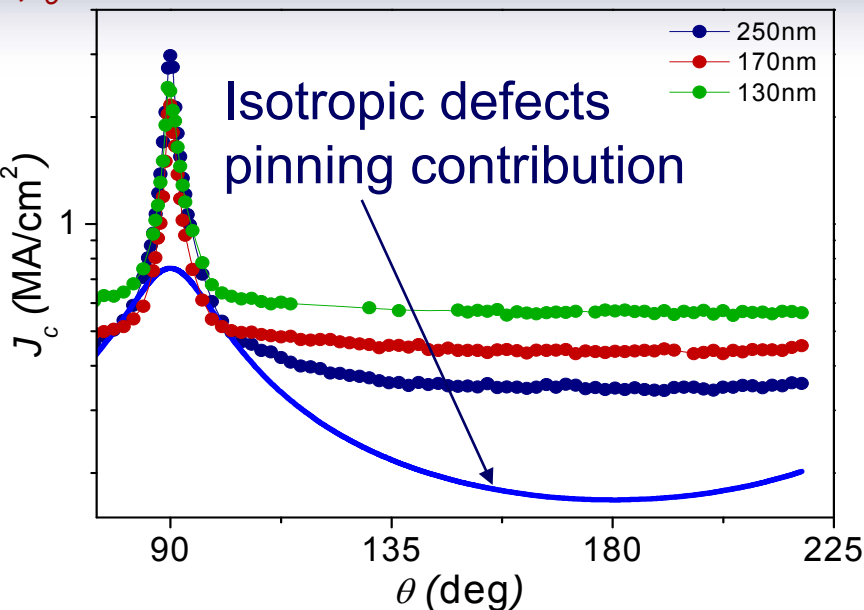


Track 2: FIB milling down to 175 nm

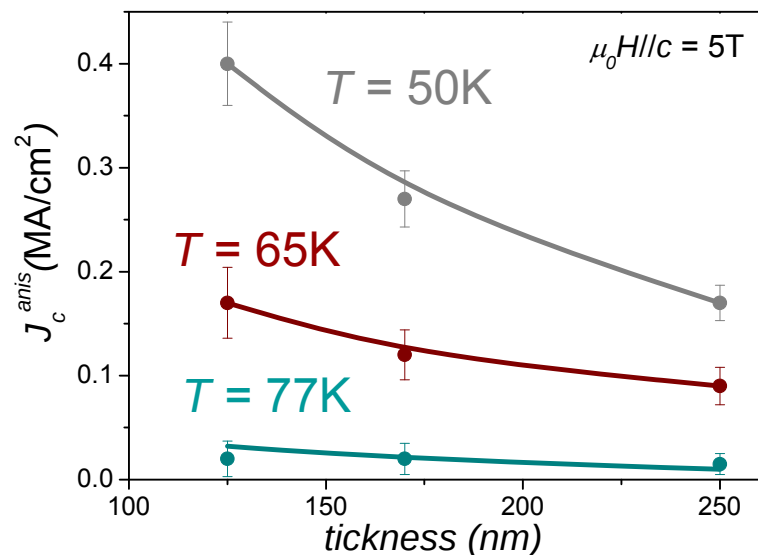
Track 3: FIB milling
down to 130nm

Angular measurements

$\mu_0 H = 5T$, $T = 50K$

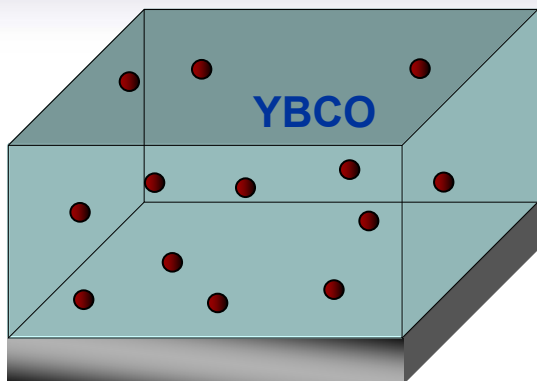


Enhanced c-axis anisotropic contribution as thickness decreases

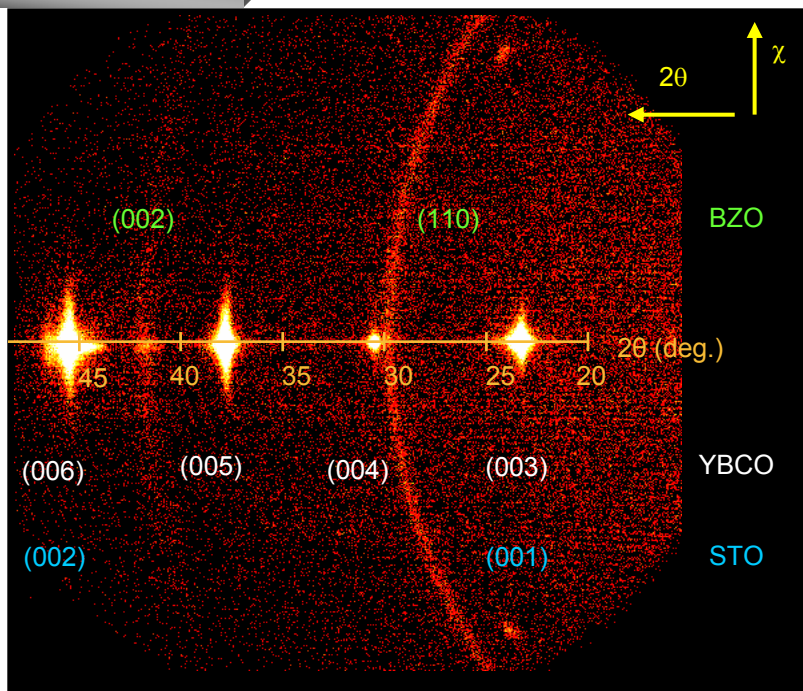


Pinning associated to defects induced by interfacial nano-particles is enhanced by reducing the YBCO thickness → Higher density of defects generated near the nano-structures

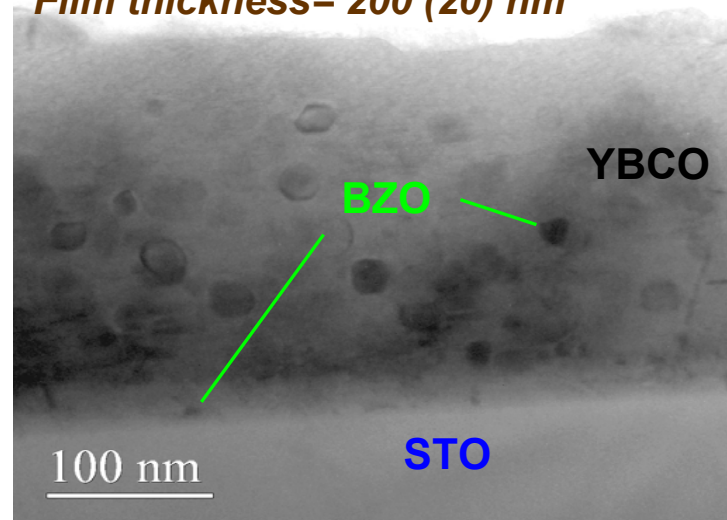
In-situ YBCO^{TFA}-BZO nanocomposites



Modification of the (Y,Ba,Cu) precursor solution by addition of Ba and Zr salts: BaZrO₃ nanodots randomly embedded



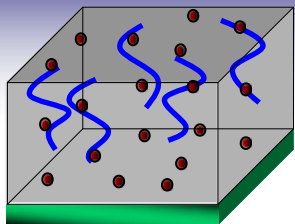
Film thickness= 200 (20) nm



➤ BZO nanodots size : 10-20 nm

Two populations of BZO coexist

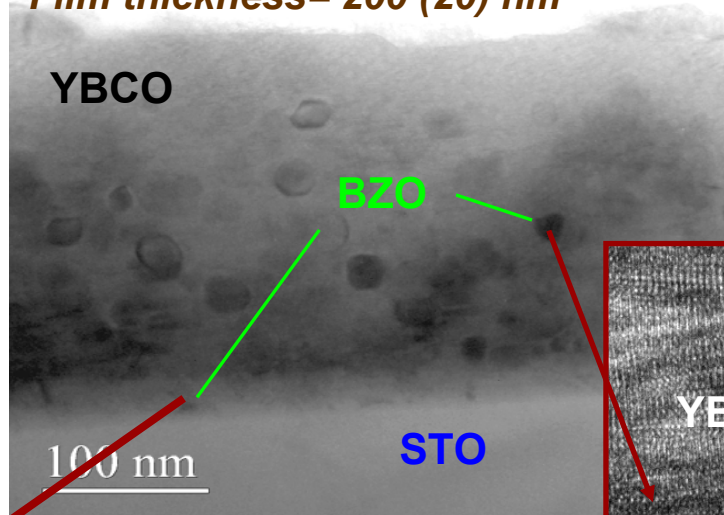
Epitaxial
Non epitaxial



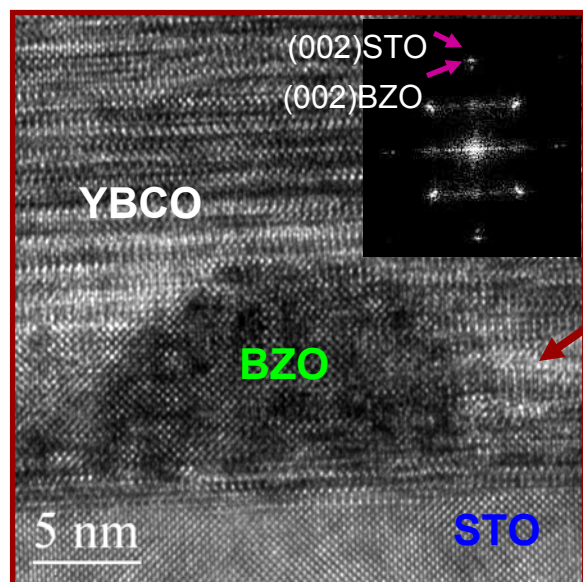
YBCO^{TFA}-BZO nanocomposites

Modification of the (Y,Ba,Cu)TFA anhydrous precursor solution by addition of Ba and Zr salts

Film thickness = 200 (20) nm

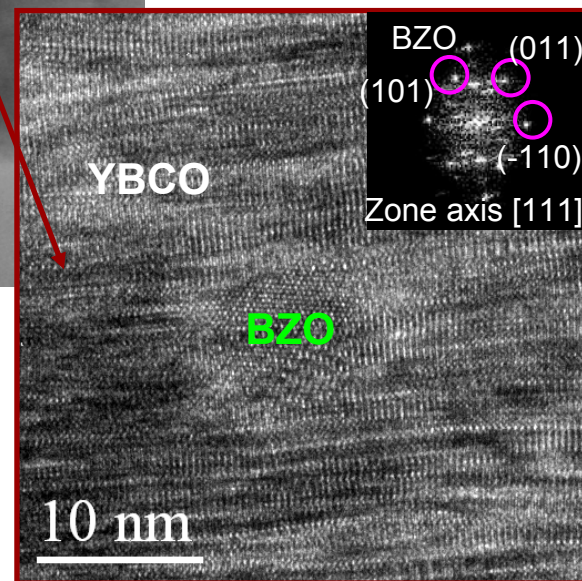


Interfacial nanodots



cube on cube **epitaxial**
relationship with YBCO matrix

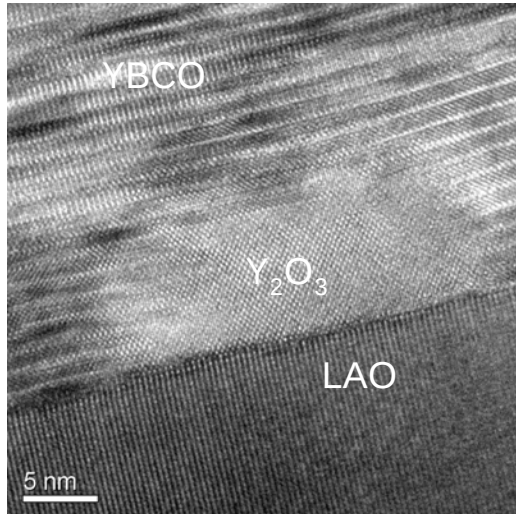
Bulk nanodots



Randomly oriented
(non-coherent with the matrix)

In-situ YBCO^{TFA}-Y₂O₃ nanocomposite

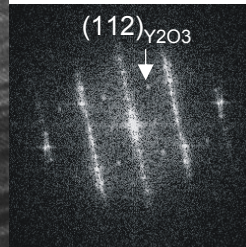
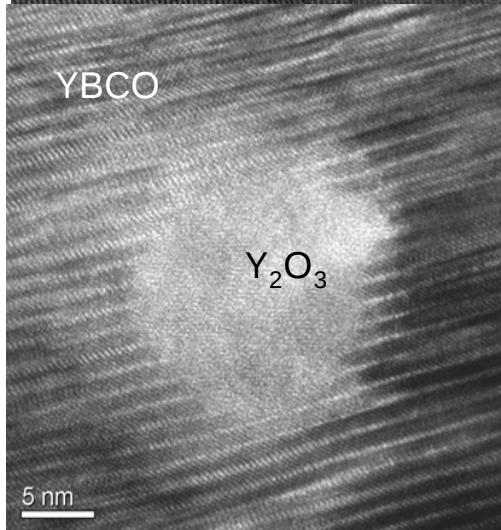
Epitaxial Y₂O₃ at the substrate interface and in the bulk



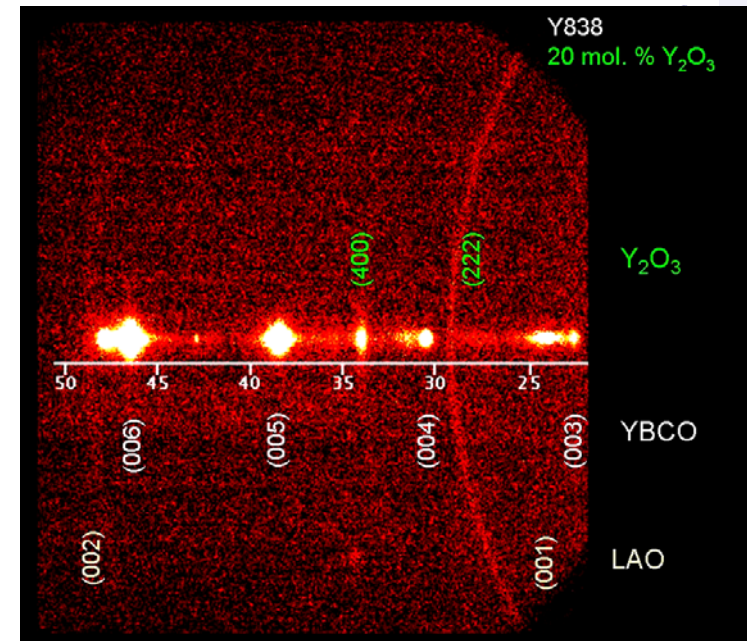
$$\varepsilon = -2.7 \%$$

$$J_c(1T, 77K) = 0.5 \text{ MA/cm}^2 \text{ for } 20 \text{ \%mol}$$

$$J_c(1T, 77K) = 0.3 \text{ MA/cm}^2 \text{ for } 10 \text{ \%mol}$$



Average size Y₂O₃: 20-25nm



Y₂O₃ polycrystalline fraction is also present...BUT not identified by TEM

$$(001)Y_2O_3 \parallel (001)YBCO$$

$$[110]Y_2O_3 \parallel [100]YBCO$$

Need of quantification of non-coherent (or random) fraction

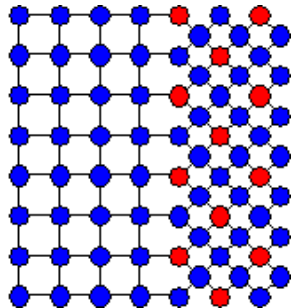
Interfaces in nanocomposites

- Can be divided, on the basis of their lattice matching, into three classes

↑ Interfacial energy

Coherent

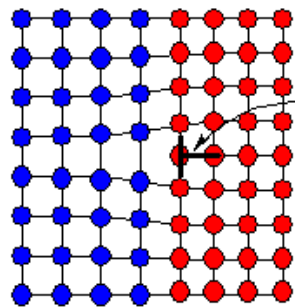
$$\gamma (\text{coherent}) = \gamma_{ch}$$



Perfect lattice matching at the interface plane

Semi-coherent

$$\gamma (\text{semi-coherent}) = \gamma_{ch} + \gamma_{st}$$



Misfit dislocation

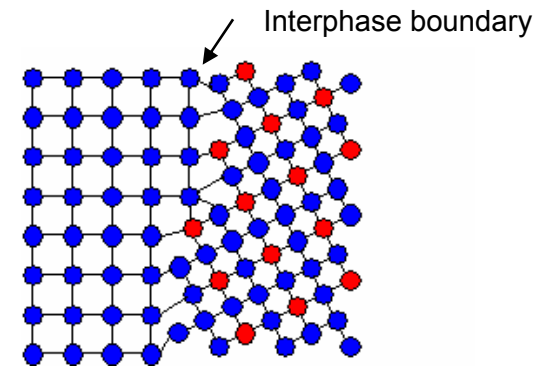
Lattice matching with strain relaxation

$$\delta = (d_A - d_B) / d_A$$

Epitaxial interfaces

Based on an orientation relationship which is specified crystallographically in terms of a pair of planes and directions:
 $\{hkl\}_A // \{hkl\}_B$ with $\langle uvw \rangle_A // \langle uvw \rangle_B$

Incoherent



NO lattice matching

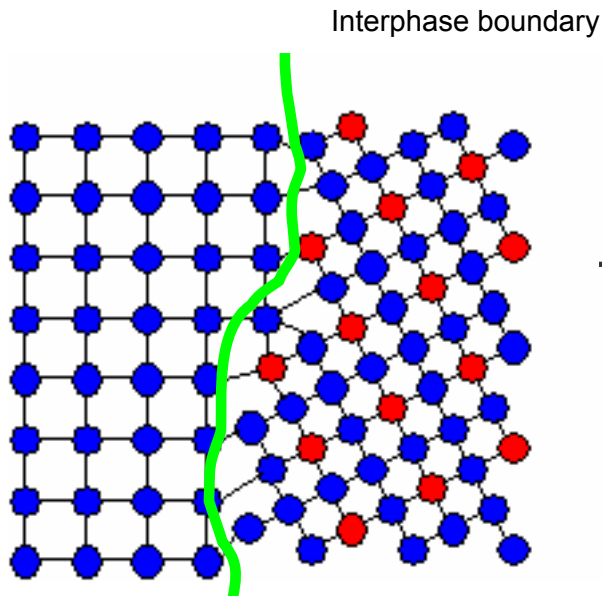
NO orientation relationship

Disordered structure

Very little is known about the detailed structure

Analogy interphase-grain boundaries

Interphase boundary

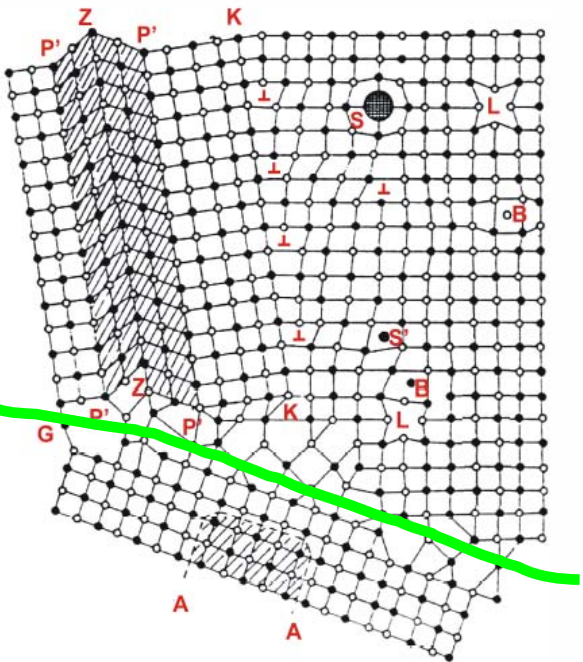


High angle grain boundary

High interfacial energy

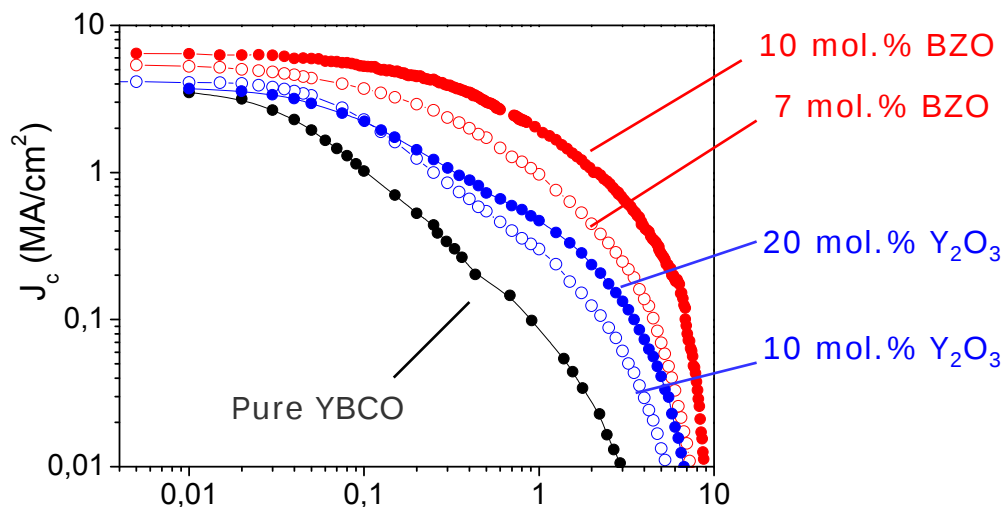
Nano-structural
defects formation

- Stacking faults
- Chemical heterogeneities
- Twinning
- Dislocations
- Point defects
- Microstresses

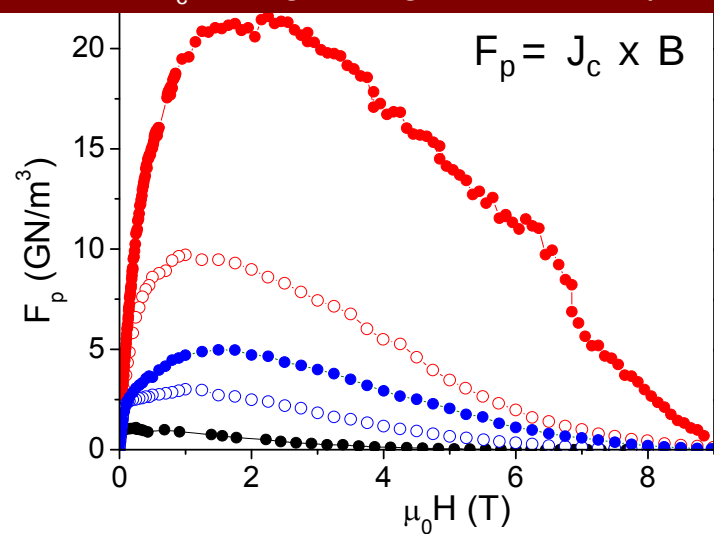


Lattice strain
(XRD)

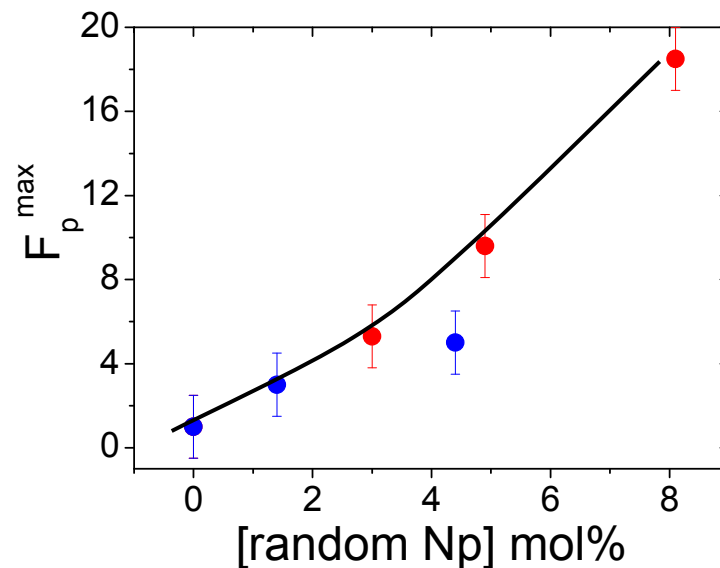
Enhanced pinning properties in SC nanocomposites are related to random Np



The strained microstructure is very effective to increase J_c at high magnetic fields (vortex pinning)



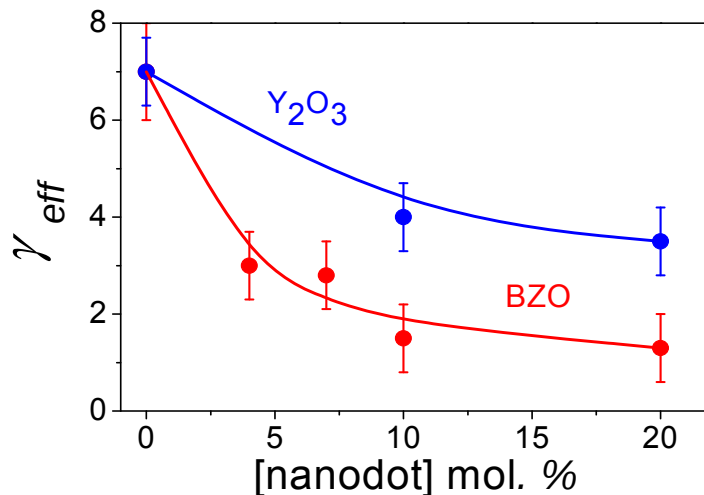
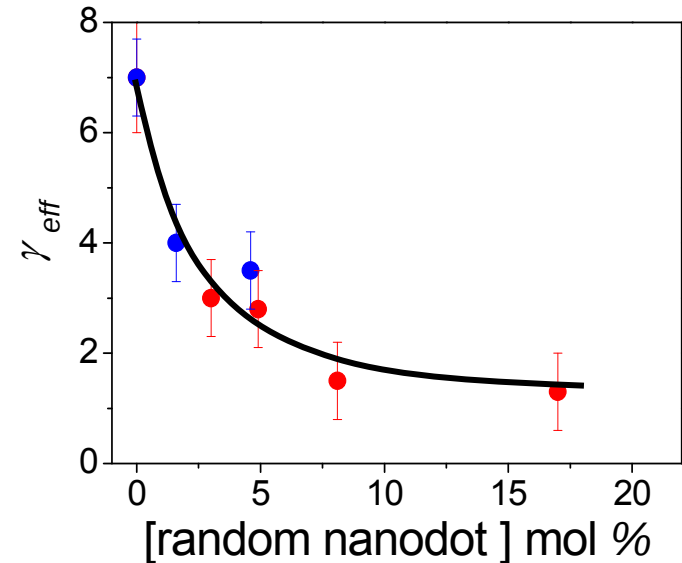
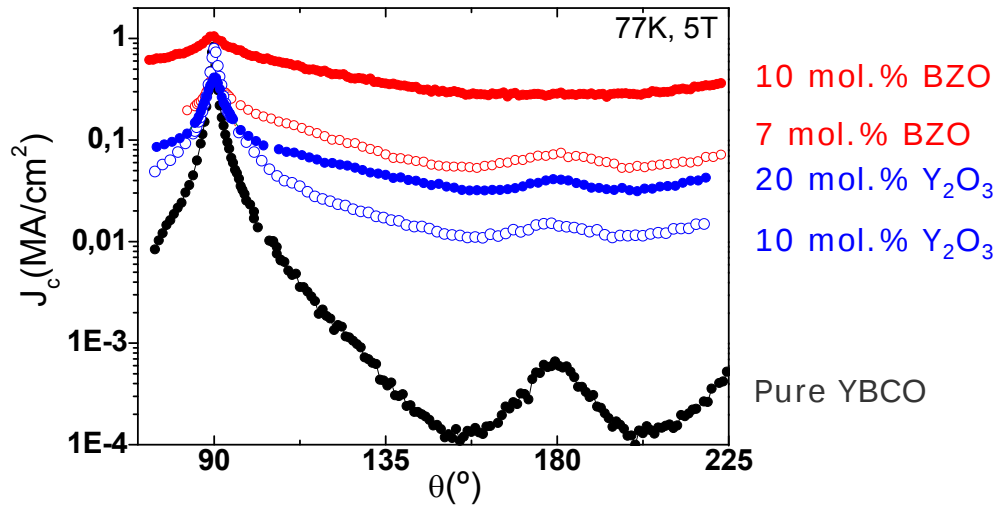
Maximum pinning force is controlled by random Np



Isotropic microstrain plays an important role in vortex pinning properties

$J_c(\theta)$ anisotropy is reduced in the nanocomposites

Vortex pinning is controlled by isotropic defects



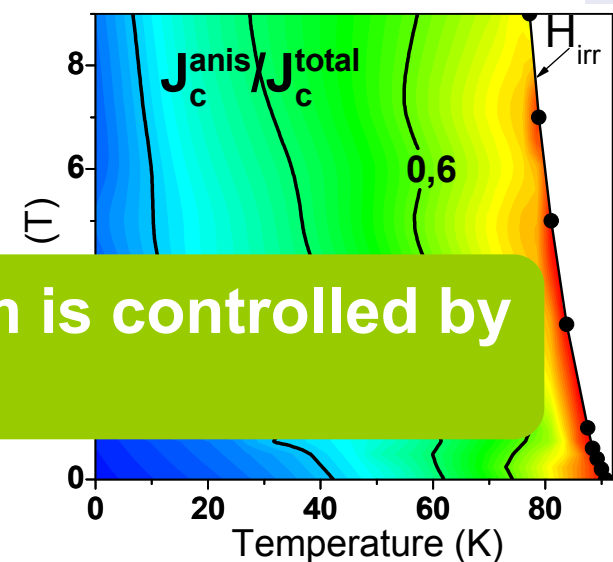
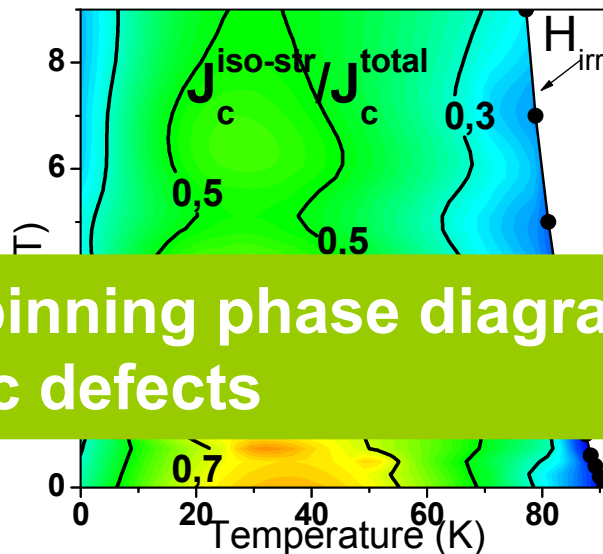
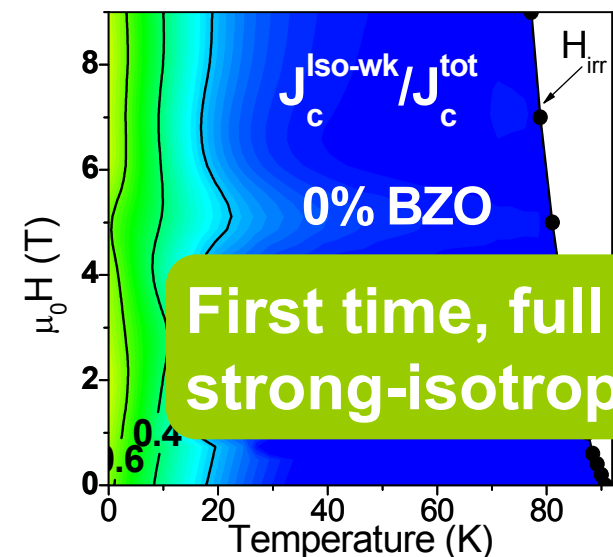
Random nanodots (isotropic microstrain) also control the effective anisotropy (γ_{eff})

Pinning regime diagrams

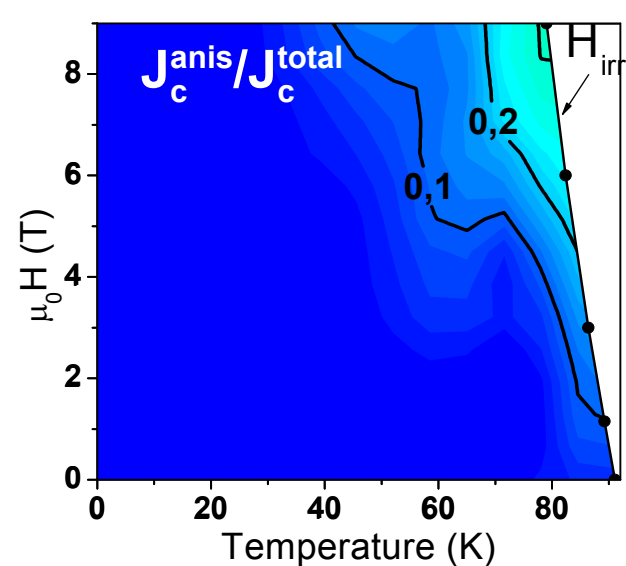
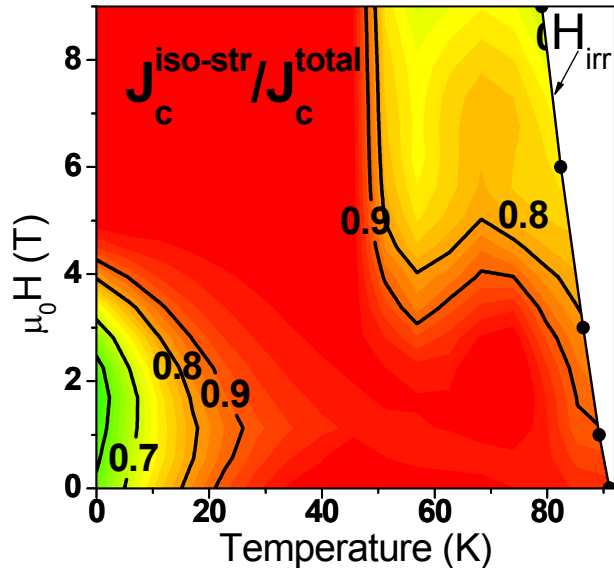
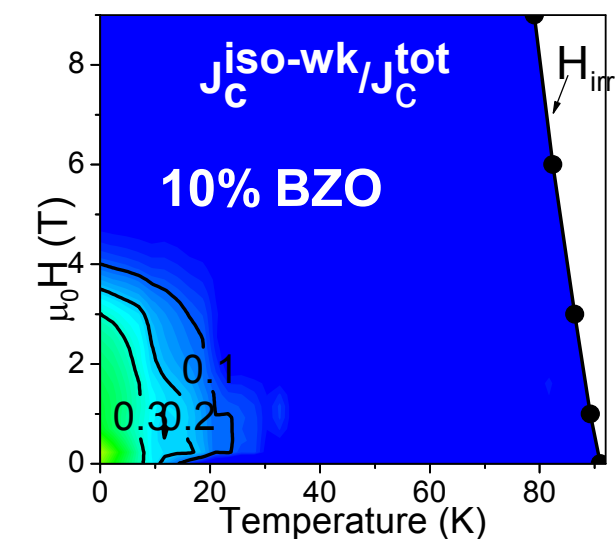
Iso-wk
contribution

Iso-str
contribution

Aniso-str
contribution



First time, full pinning phase diagram is controlled by strong-isotropic defects



Conclusions and Outlook

- **Chemical solution deposition** is a versatile technique to generate artificial pinning structures.
Complementary with PLD?
- The methodology to analyze **vortex pinning contributions** can be **used for PLD nanocomposites**.
- **Interfacial nanostructures** are successfully grown by CSD and c-axis anisotropic defects are artificially introduced in YBCO films. **Can be combined with PLD?**
- CSD **nanocomposites** are very promising, vortex pinning is controlled by strain generated by isotropic defects. **Strain in self-organized PLD nanorods?**
- **Magnetic nanostructures** have been introduced in YBCO films showing an enhancement of vortex pinning
- We need to use the **nanoscale imaging** methods to correlate vortex pinning with APC